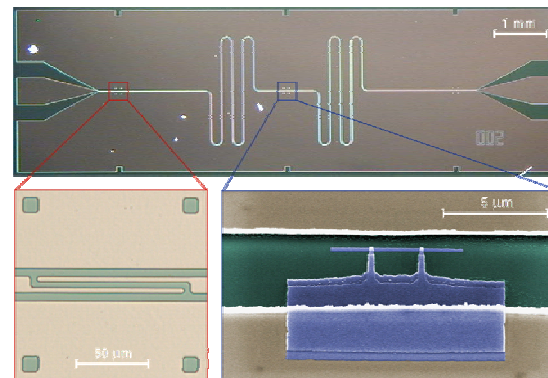
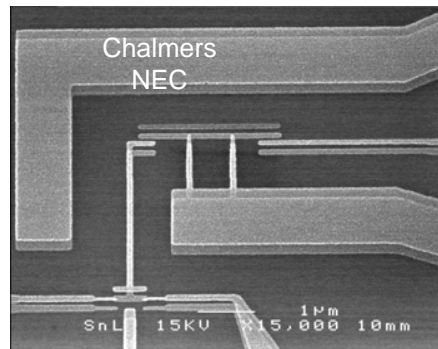


Superconducting Qubits

Andreas Wallraff

Department of Applied Physics, Yale University



with supporting material from:

M. Devoret, D. Esteve, S. Girvin, J. Mooij, R. Schoelkopf, L. Vandersypen

Motivation



long term goals:

- **build a quantum computer**
- **solve computationally hard problems**

current goals for solid state implementations:

- build scalable macroscopic quantum circuits
- control open quantum systems
- investigate quantum measurement process
- learn about decoherence in solid state systems

Schematic of a Generic Quantum Processor



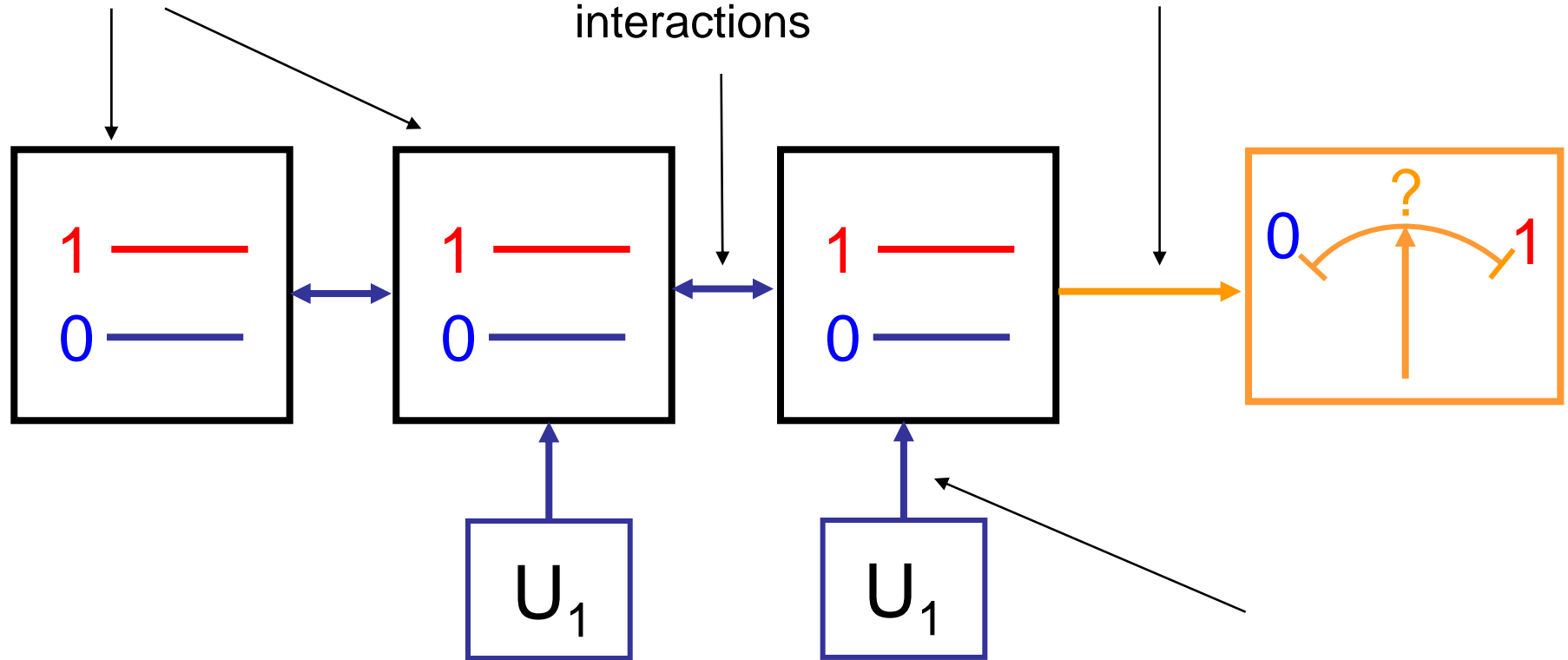
2 level systems:

qubits

2 qubit gates:

controlled interactions

readout



single qubit gates

with excellent gate, readout, ... accuracy for Q.C.

Outline

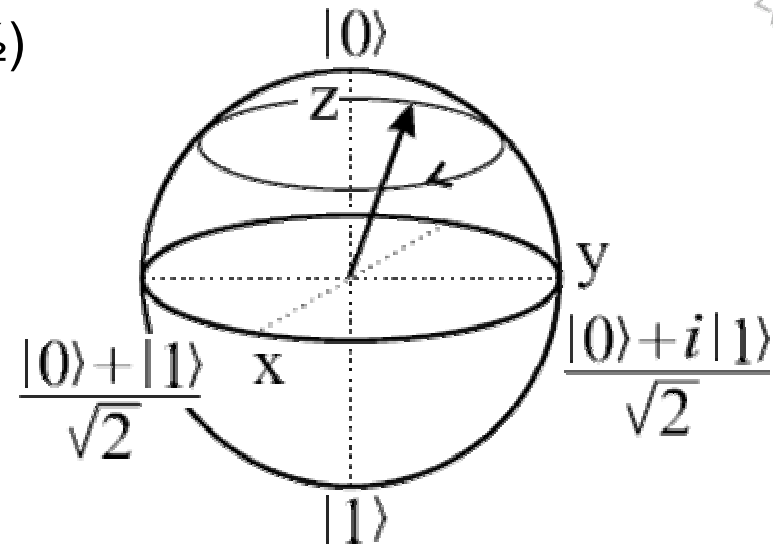
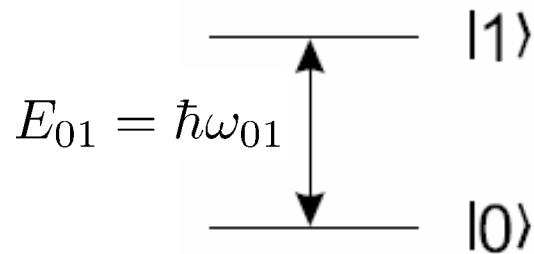


- how to make qubits from superconducting circuits
- realizations of superconducting qubits
- controlling qubits
- coherence/decoherence
- qubit readouts and measurements
- coupled qubits
- conclusions



A Generic Qubit

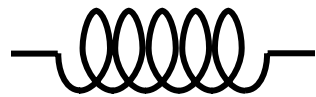
two-level quantum system (a spin $\frac{1}{2}$)



DiVincenzo criteria:

- existence of quantum two level system (a qubit)
- qubit initialization (reset)
- qubit coherence (no dissipation, no dephasing)
- qubit control (gate operations)
- qubit readout

Building Qubits with Integrated Circuits



inductor



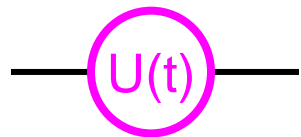
capacitor



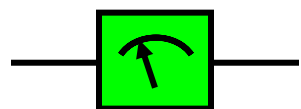
resistor



nonlinear element



voltage source



voltmeters

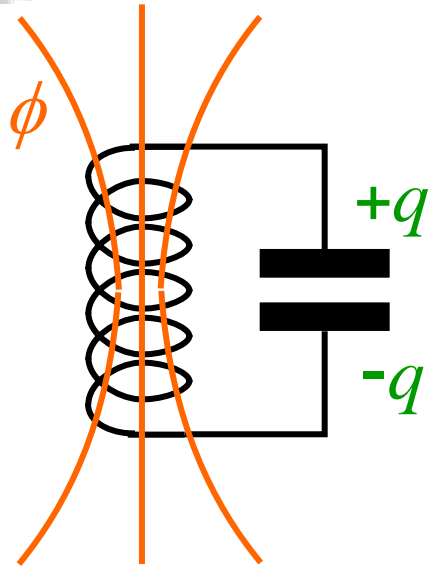
requirements for quantum circuits:

- low dissipation
- non-linear (non-dissipative elements)
- low (thermal) noise

a solution:

- use superconductors
- use Josephson tunnel junctions
- operate at low temperatures

LC Oscillator as a Quantum Circuit



$$[\phi, q] = i\hbar$$

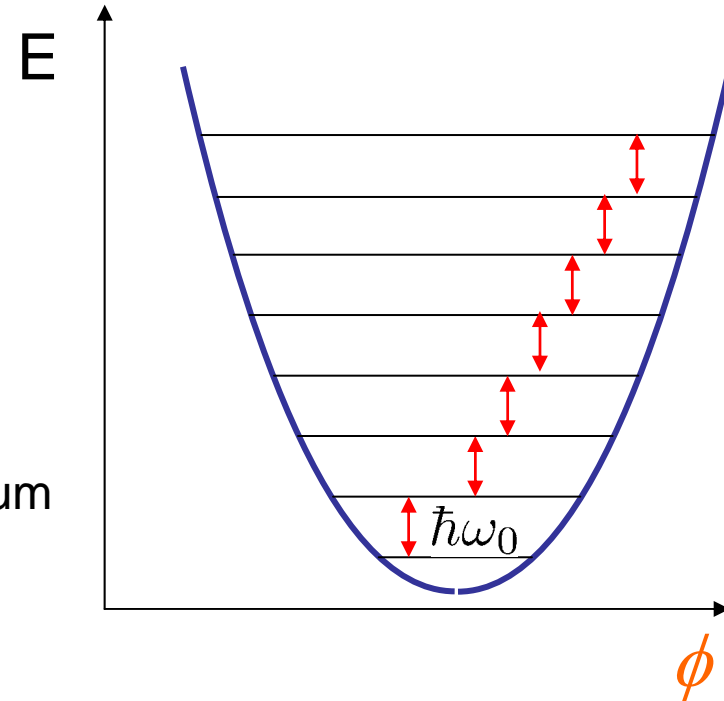
position momentum

hamiltonian

$$H = \frac{\phi^2}{2L} + \frac{q^2}{2C}$$

$$\omega_0 = 1/\sqrt{LC}$$

$$H = \hbar\omega_0 \left(a^\dagger a + \frac{1}{2} \right)$$



low temperature required:

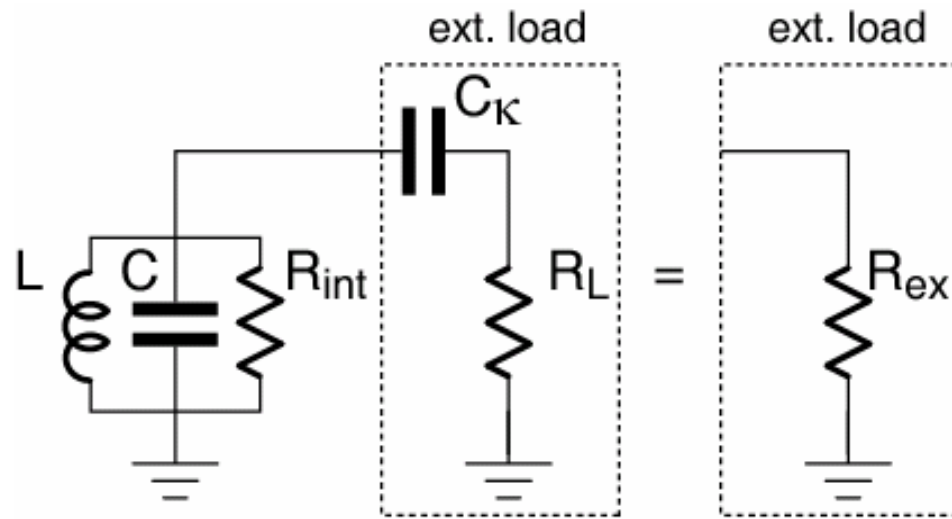
$$\hbar\omega_0 \gg k_B T$$

1 GHz ~ 50 mK

problem I: equally spaced energy levels (linearity)



Dissipation in an LC Oscillator



internal losses: R_{int}
conductor, dielectric

external losses: R_{ext}
radiation, coupling

total losses $\frac{1}{R} = \frac{1}{R_{int}} + \frac{1}{R_{ext}}$

$$Z = \sqrt{\frac{L}{C}}$$

$$Q = \frac{R}{Z} = \omega_0 RC$$

$$\Gamma_1 = \frac{\omega_0}{Q} = \frac{1}{RC}$$

impedance

quality factor

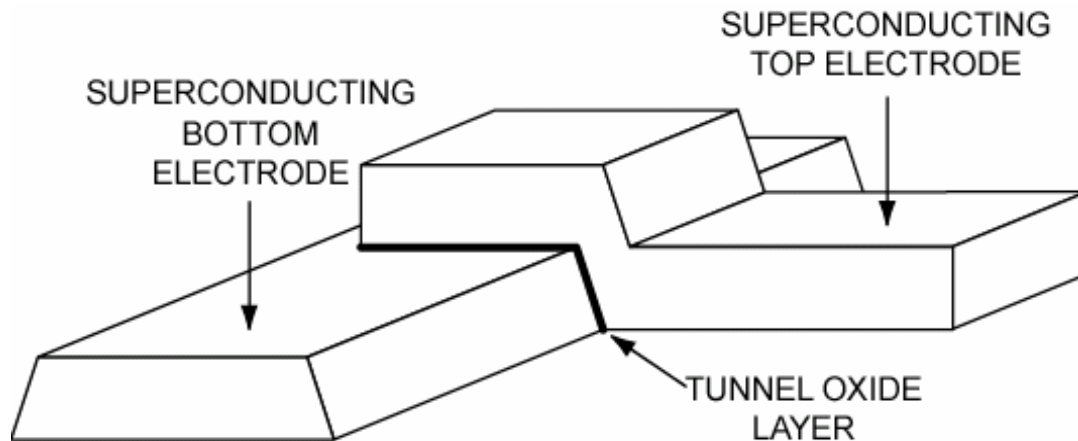
excited state decay rate

problem II: avoid internal and external dissipation

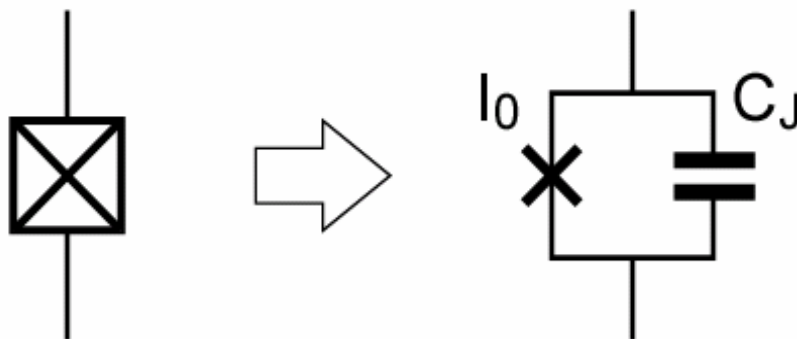
A Superconducting Nonlinear Element



Josephson junction



- superconductors: Nb, Al
- tunnel barrier: AlO_x

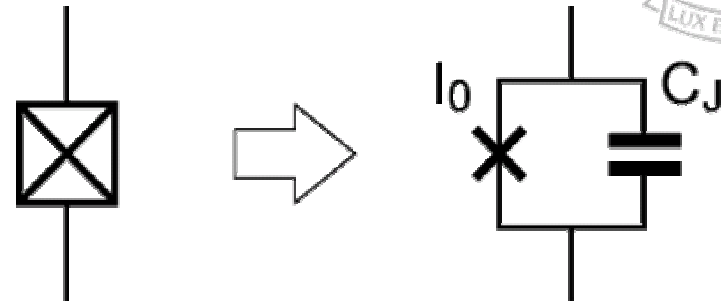


- critical current I_0
- junction capacitance C_J

The Josephson Junction



a nonlinear inductor without dissipation



nonlinear current flux relation:

$$I = I_0 \sin [2\pi\Phi(t)/\Phi_0] = I_0 \sin \delta$$

gauge inv. phase difference:

$$\delta = 2\pi\Phi(t)/\Phi_0$$

nonlinear Josephson inductance:

$$L_J(\delta) = \left(\frac{\partial I}{\partial \Phi} \right)^{-1} = \frac{\Phi_0}{2\pi I_0 \cos \delta} \stackrel{L_{J0}}{=} \frac{1}{2\pi I_0 \cos \delta}$$

voltage:

$$V = \frac{d\Phi}{dt} = \frac{\Phi_0}{2\pi} \dot{\delta}$$

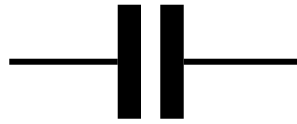
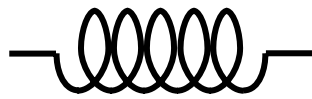
Josephson energy:

$$E_{J0} \stackrel{E}{=} \frac{I_0 \Phi_0}{2\pi} \cos \delta$$

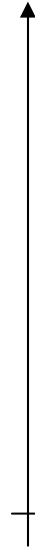
Building Blocks for Qubits



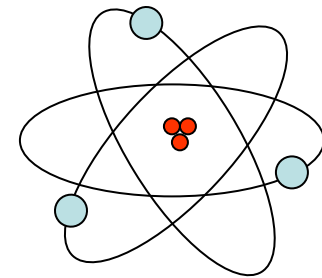
all ingredients available:



E



artificial atom

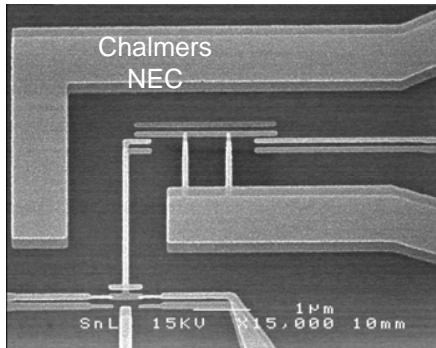


~ 0.5 K (10 GHz)

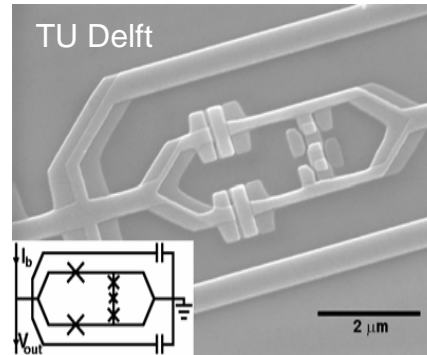
Superconducting Qubits



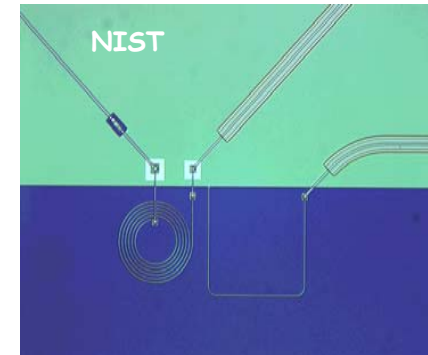
charge



flux



phase

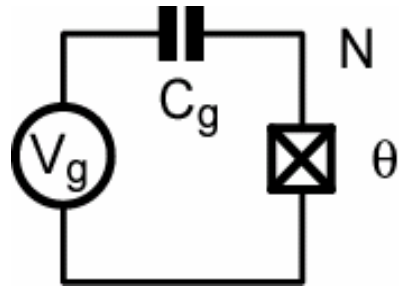


classified by their control parameter



Charge Qubits

Cooper pair box

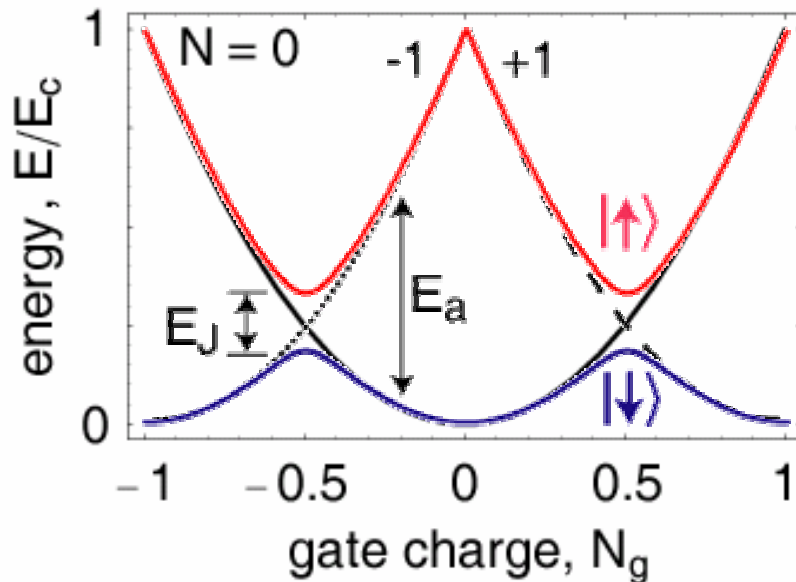


$$[\theta, N] = i$$

$$H = E_C (N - N_g)^2 - E_J \cos \theta$$

electrostatic energy

Josephson energy



charging energy $E_C = \frac{(2e)^2}{2(C_J + C_g)}$

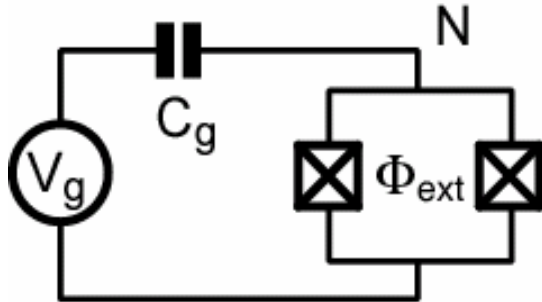
Josephson energy $E_J = \frac{I_0 \Phi_0}{2\pi} = \frac{h\Delta}{8e^2 R_J}$

gate charge $N_g = \frac{C_g V_g}{2e}$

Tunable Charge Qubits



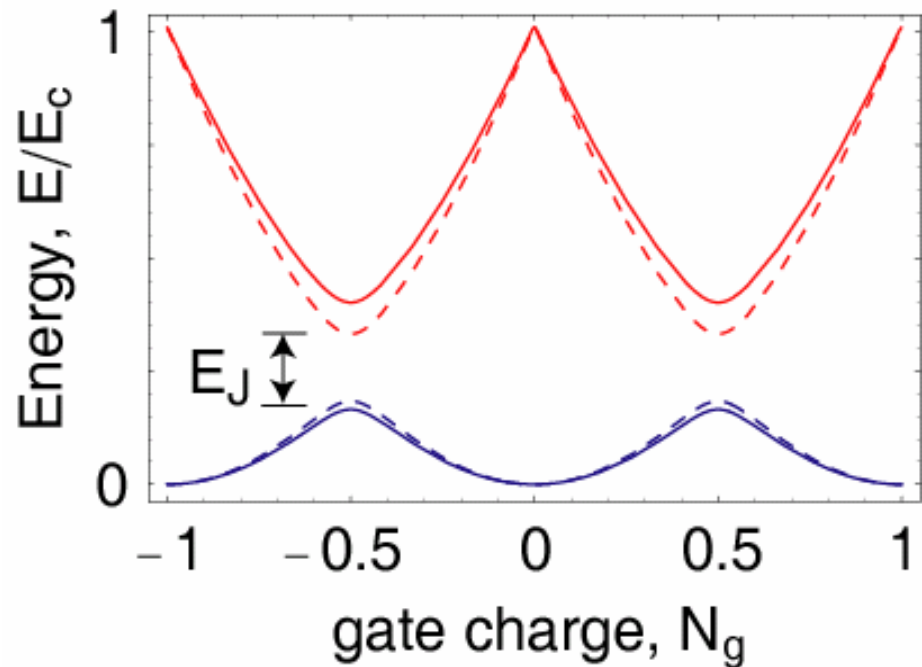
split Cooper pair box



$$H = E_C (N - N_g)^2 - E_{J,\max} \cos\left(\pi \frac{\Phi_{\text{ext}}}{\Phi_0}\right)$$

SQUID modulation of Josephson energy

$$E_J = E_{J,\max} \cos\left(\pi \frac{\Phi_{\text{ext}}}{\Phi_0}\right)$$



Cooper Pair Box Energy Levels

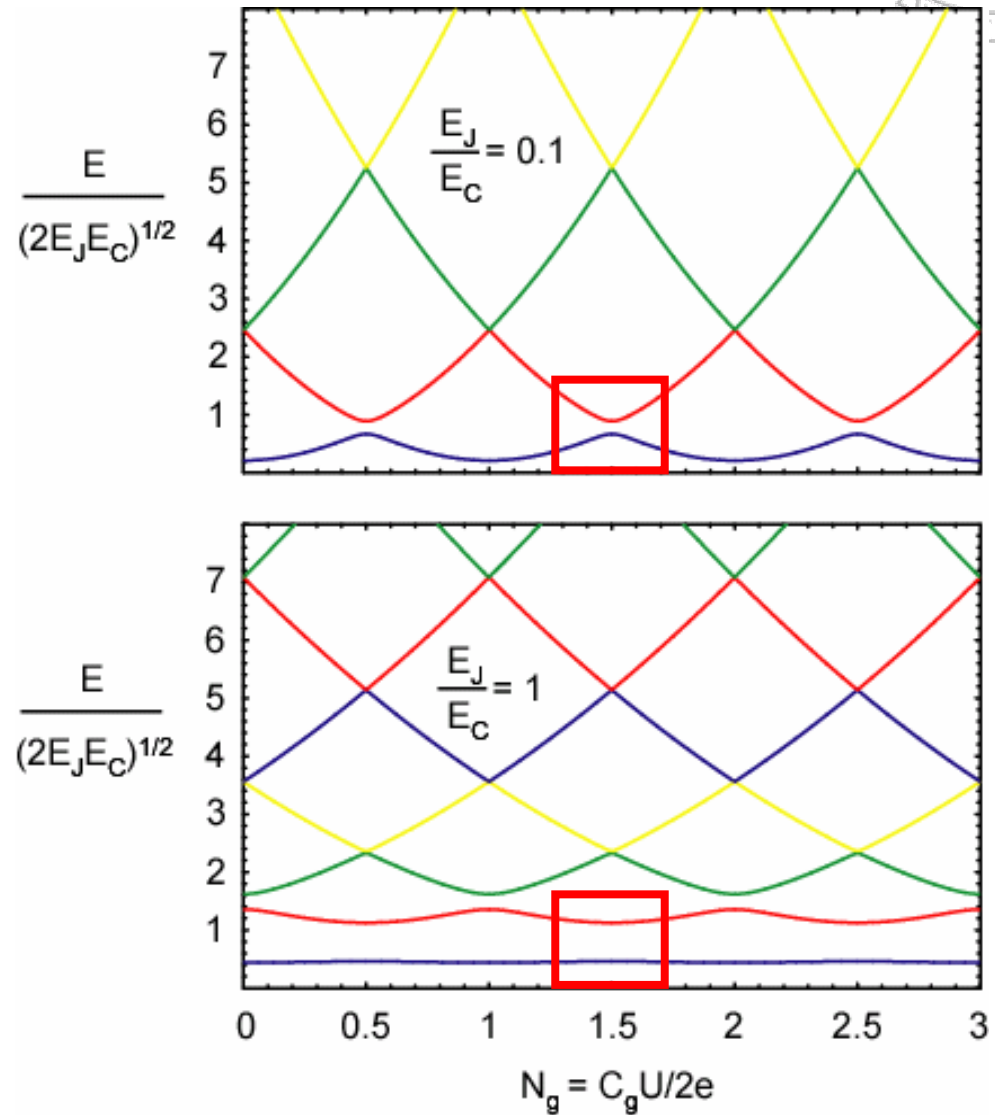


$$E_J \gg E_C$$

level separation for arbitrary charging energy and Josephson energy

$$E_J \sim E_C$$

two-state approximation close to charge degeneracy



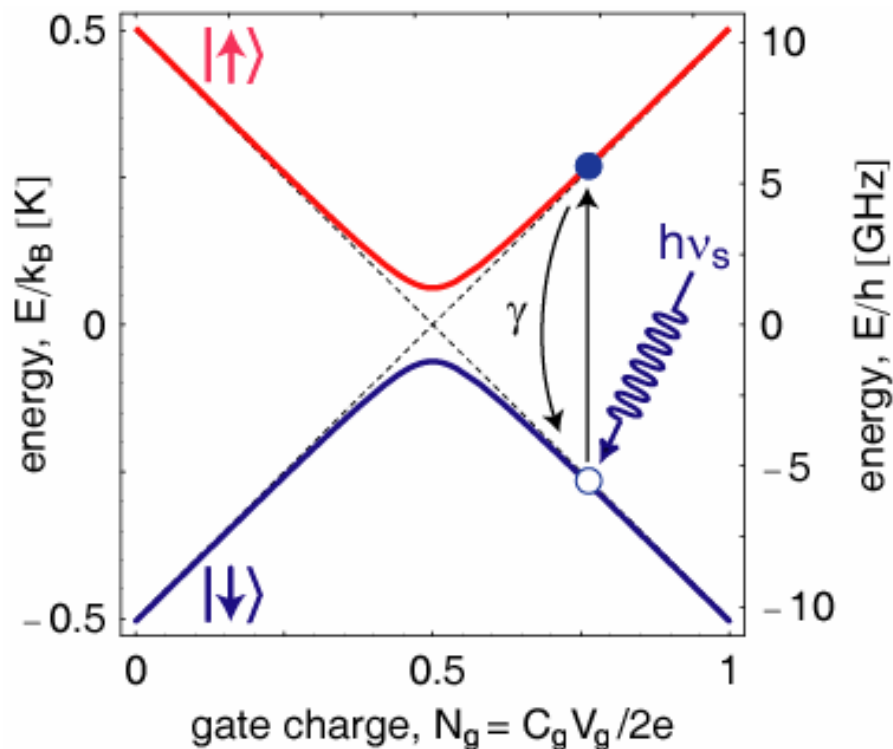


Two-State Approximation

2-state Hamiltonian and level separation:

$$H = -1/2 (E_{el} \sigma_x + E_J \sigma_z)$$

$$E = \sqrt{E_{el}^2 + E_J^2}$$



in-situ controllable parameters:

$$E_{el} = E_C (1/2 - N_g)$$

$$E_J = E_{J,max} \cos(\pi \Phi_{ext} / \Phi_0)$$

$E_C, E_{J,max}$ engineerable in fabrication

excited state decay rates $\Gamma_1 < 1 \text{ MHz}$

K. Lehnert *et al.* *PRL* **90**, 027002 (2003).

Nakamura, Pashkin, Tsai *et al.* *Nature* **398**, 421, 425 (1999, 2003, 2003)

Control of Charge Qubit



effective hamiltonian

$$H_{\text{qubit}} = -E_z (\sigma_z + X_{\text{control}} \sigma_x)$$

energy splitting

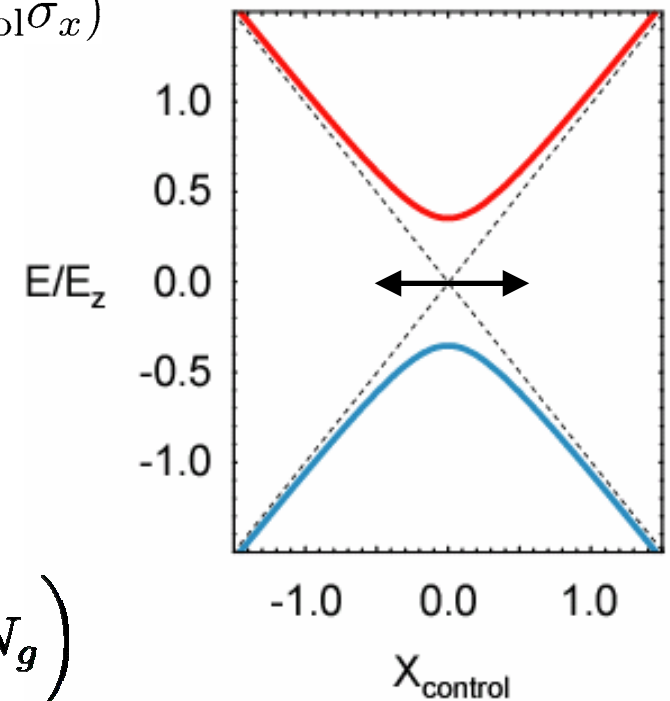
$$E_z = \frac{E_J}{2}$$

control parameter

$$X_{\text{control}} = 2 \frac{E_C}{E_J} \left(\frac{1}{2} - N_g \right)$$

gate charge

$$N_g = \frac{C_g V_g}{2e}$$

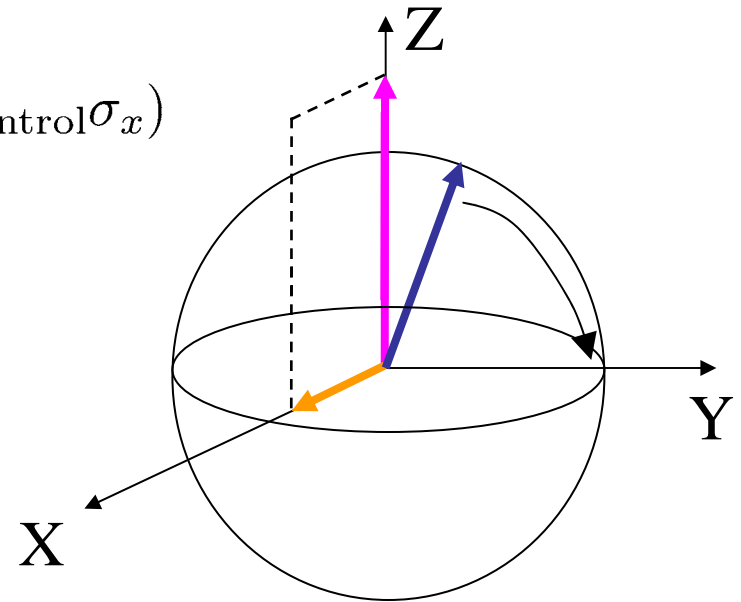


Control of Charge Qubit



effective hamiltonian

$$H_{\text{qubit}} = -E_z (\sigma_z + X_{\text{control}} \sigma_x)$$



energy splitting

$$E_z = \frac{E_J}{2}$$

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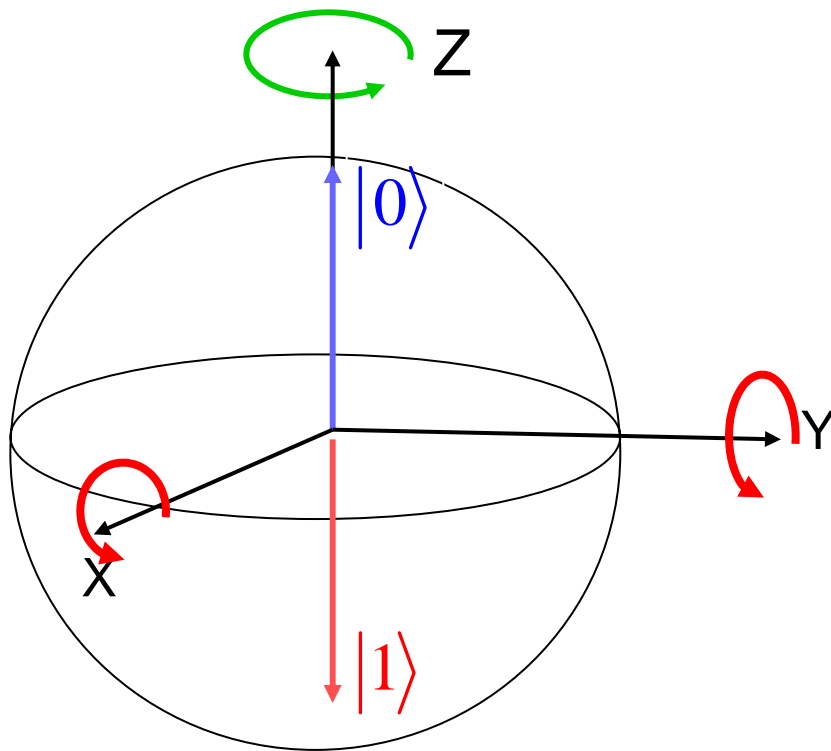
gate charge

$$N_g = \frac{C_g V_g}{2e}$$

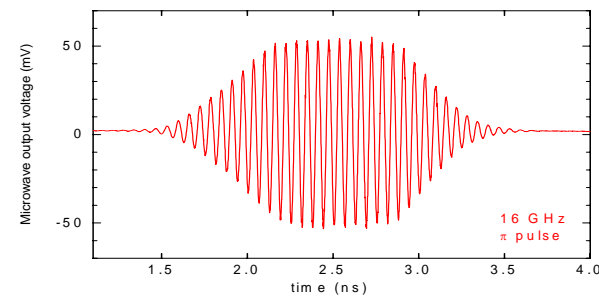
Single Qubit Control



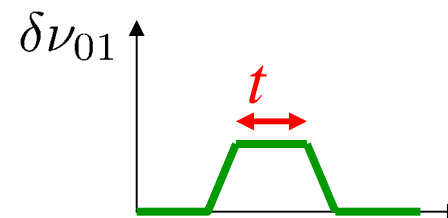
Bloch sphere representation of single qubit manipulation



x,y rotations by microwave pulses



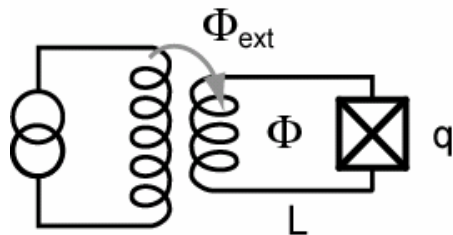
z rotations by adiabatic pulses



Flux Qubits



radio frequency superconducting quantum interference device (RF-SQUID)



$$[\Phi, q] = i\hbar$$

$$H = \frac{q^2}{2C_J} + \frac{\Phi^2}{2L} - E_J \cos \left[2\pi \frac{\Phi - \Phi_{\text{ext}}}{\Phi_0} \right]$$

kinetic energy

potential energy

charging energy

$$E_C = \frac{(2e)^2}{2C_J}$$

inductive energy

$$E_L = \frac{\Phi_0^2}{2L}$$

Josephson energy

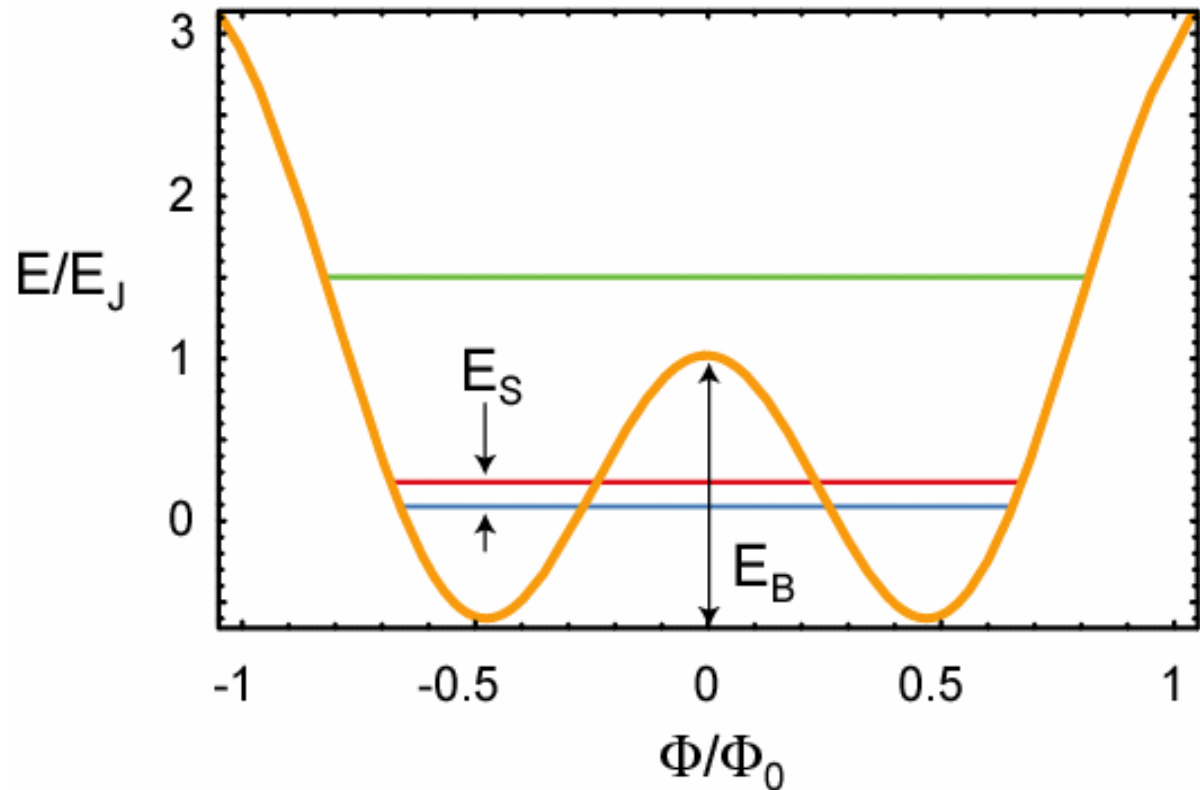
$$E_J = \frac{I_0 \Phi_0}{2\pi} = \frac{h\Delta}{8e^2 R_J}$$

RF-SQUID Potential



parabolic potential
with cosine corrugation

- $\Phi_{\text{ext}} = \Phi_0/2$
- $E_J \gg E_C$



energy level splitting at $\Phi_{\text{ext}} = \Phi_0/2$

bias flux dependence

$$E_S \propto \eta \sqrt{E_B E_{CJ}} \exp\left(-\xi \sqrt{\frac{E_B}{E_{CJ}}}\right)$$

$$E_S \propto \zeta \frac{\Phi_0^2}{2L} \left(\frac{1}{2} - \frac{\Phi_{\text{ext}}}{\Phi_0}\right)$$

Control of Flux Qubits



effective hamiltonian

$$H_{\text{qubit}} = -E_z (\sigma_Z + X_{\text{control}} \sigma_X)$$

splitting energy

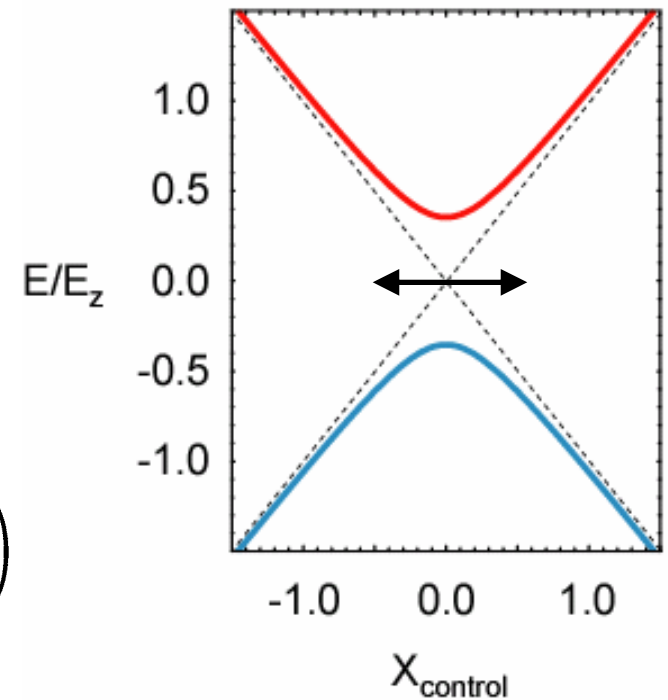
$$E_z = \frac{E_S}{2}$$

control parameter

$$X_{\text{control}} = 2 \frac{E_L}{E_S} \left(\frac{1}{2} - N_{\Phi} \right)$$

flux frustration

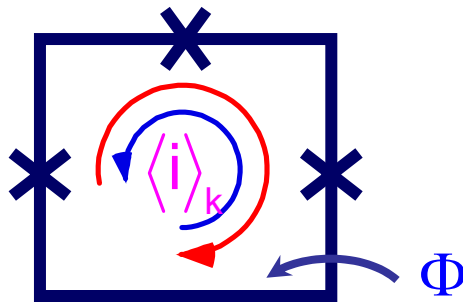
$$N_{\Phi} = \frac{\Phi_{\text{ext}}}{\Phi_0}$$





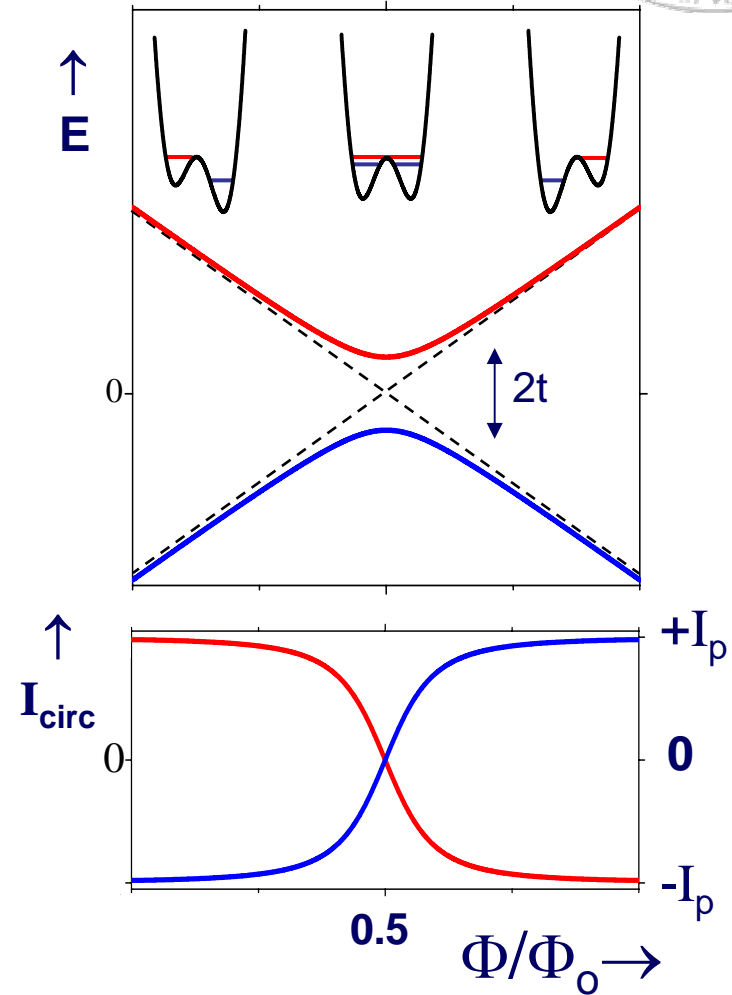
Variation of the Flux Qubit

persistent-current quantum bit:
flux qubit with three junctions,
small geometric loop inductance



$$H = h\sigma_z + t\sigma_x$$

with $h = (\Phi/\Phi_0 - 0.5) \Phi_0 I_p$



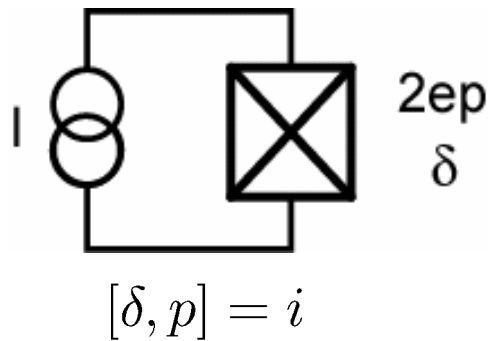
J. E. Mooij, T. P. Orlando, ... , C. H. van der Wal and S. Lloyd, *Science* **285**, 1036 (1999)

C. H. van der Wal, A. C. J. ter Haar, ... , S. Lloyd and J. E. Mooij, *Science* **290**, 773 (2000).

Phase Qubits



current biased junction



$$H = \frac{(2e)^2}{2C_J} p^2 - I \frac{\Phi_0}{2\pi} \delta - \frac{I_0 \Phi_0}{2\pi} \cos \delta$$

kinetic energy potential energy

charging energy

$$E_C = \frac{(2e)^2}{2C_J}$$

Josephson energy

$$E_J = \frac{I_0 \Phi_0}{2\pi} = \frac{h\Delta}{8e^2 R_J}$$

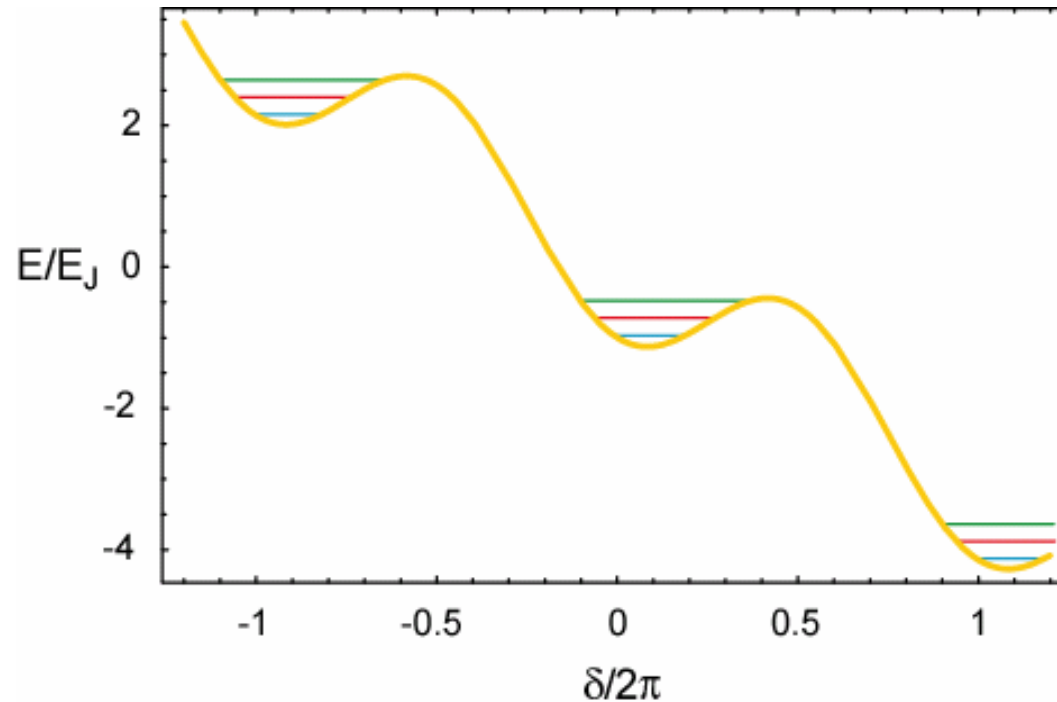
bias current

$$I$$

Potential of Current Biased Junction



particle in a washboard potential



potential

$$U(\delta) = -I \frac{\Phi_0}{2\pi} \delta - \frac{I_0 \Phi_0}{2\pi} \cos \delta$$

Energy level quantization



cubic potential near $I = I_0$

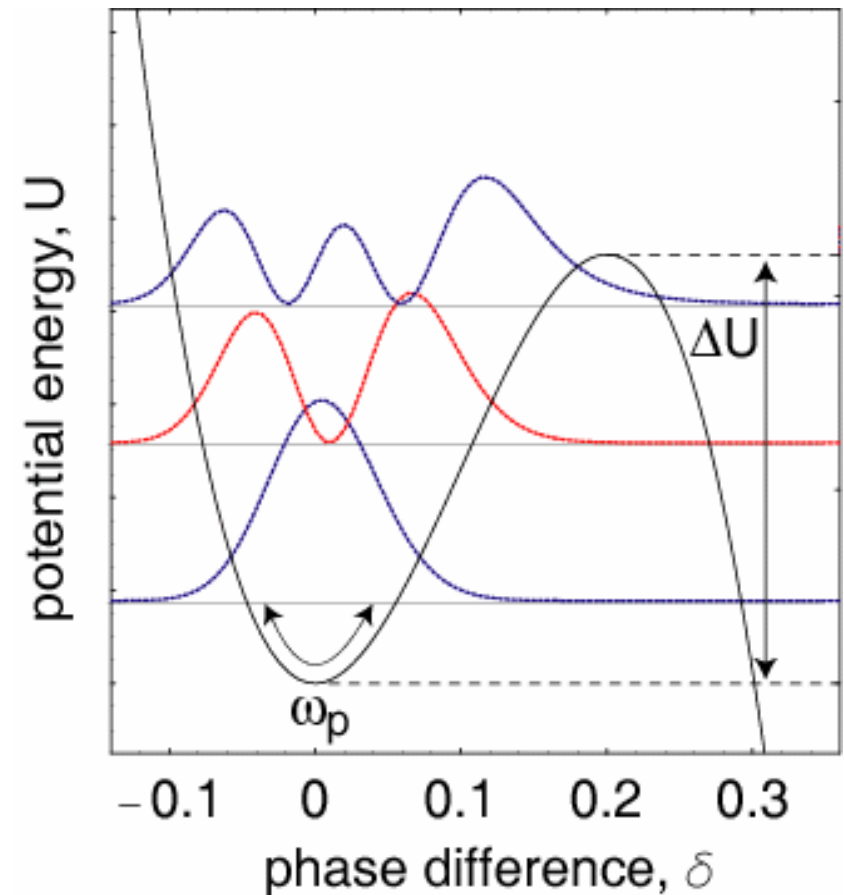
barrier height

$$\Delta U = \frac{2\sqrt{2}}{3} E_J \left(1 - \frac{I}{I_0}\right)^{3/2}$$

oscillation frequency

$$\omega_p = \frac{1}{\sqrt{L J_0 C_J}} \left[1 - \left(\frac{I}{I_0}\right)^2\right]^{1/4}$$

use eigenstates as basis states of qubit



Control of Phase Qubits



effective hamiltonian

$$H_{\text{qubit}} = \frac{1}{2}\hbar\omega_{01}\sigma_Z + \sqrt{\frac{\hbar}{2\omega_{01}C_J}}\Delta I(\sigma_X + \chi\sigma_Z)$$

'splitting' energy

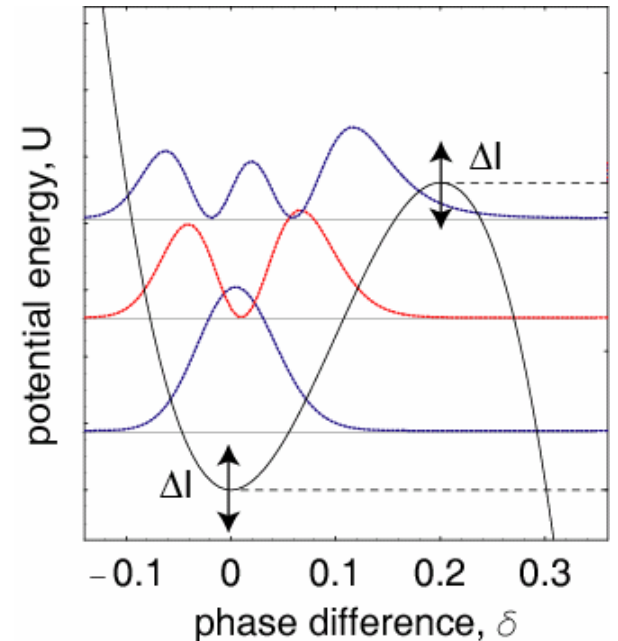
$$\hbar\omega_{01}$$

control parameter

$$\sqrt{\frac{\hbar}{2\omega_{01}C_J}}\Delta I$$

bias current

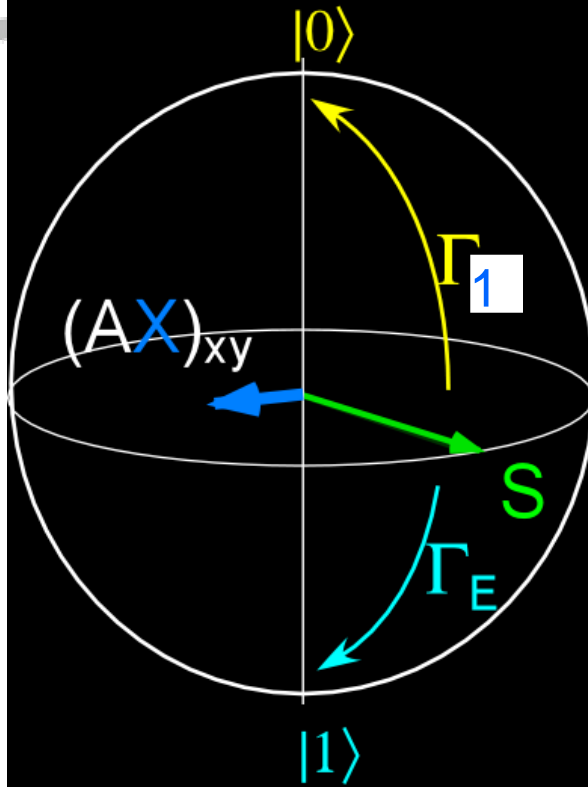
$$\Delta I = I - I_0$$



operations:

- $\Delta I \propto \sin \omega_{01}t$ performs σ_X operations
- slow variations in ΔI perform σ_Z operations

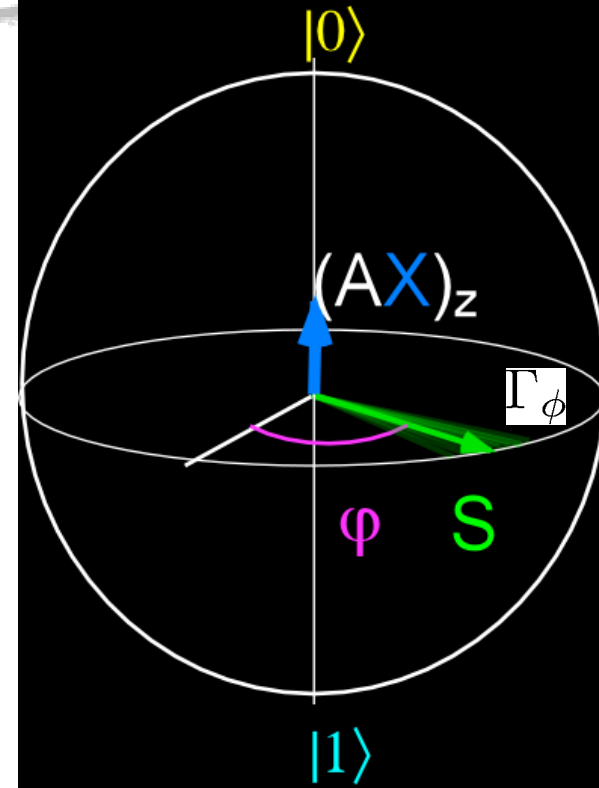
Decoherence: Relaxation and Dephasing



relaxation: transverse fluctuations at qubit transition frequency

life time

$$T_1 = \Gamma_1^{-1}$$

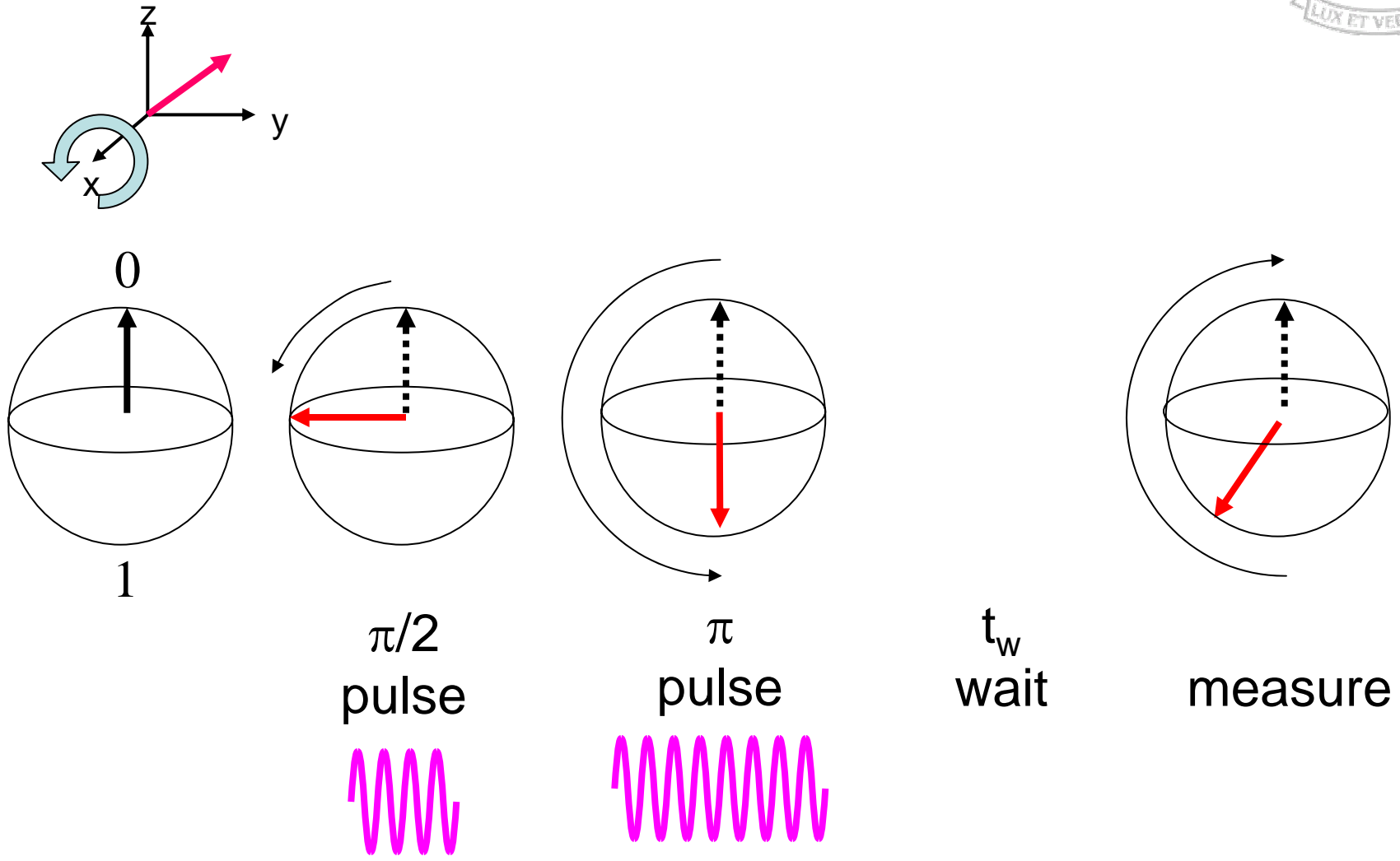


dephasing: parallel fluctuations (in qubit level sep.) at low frequencies

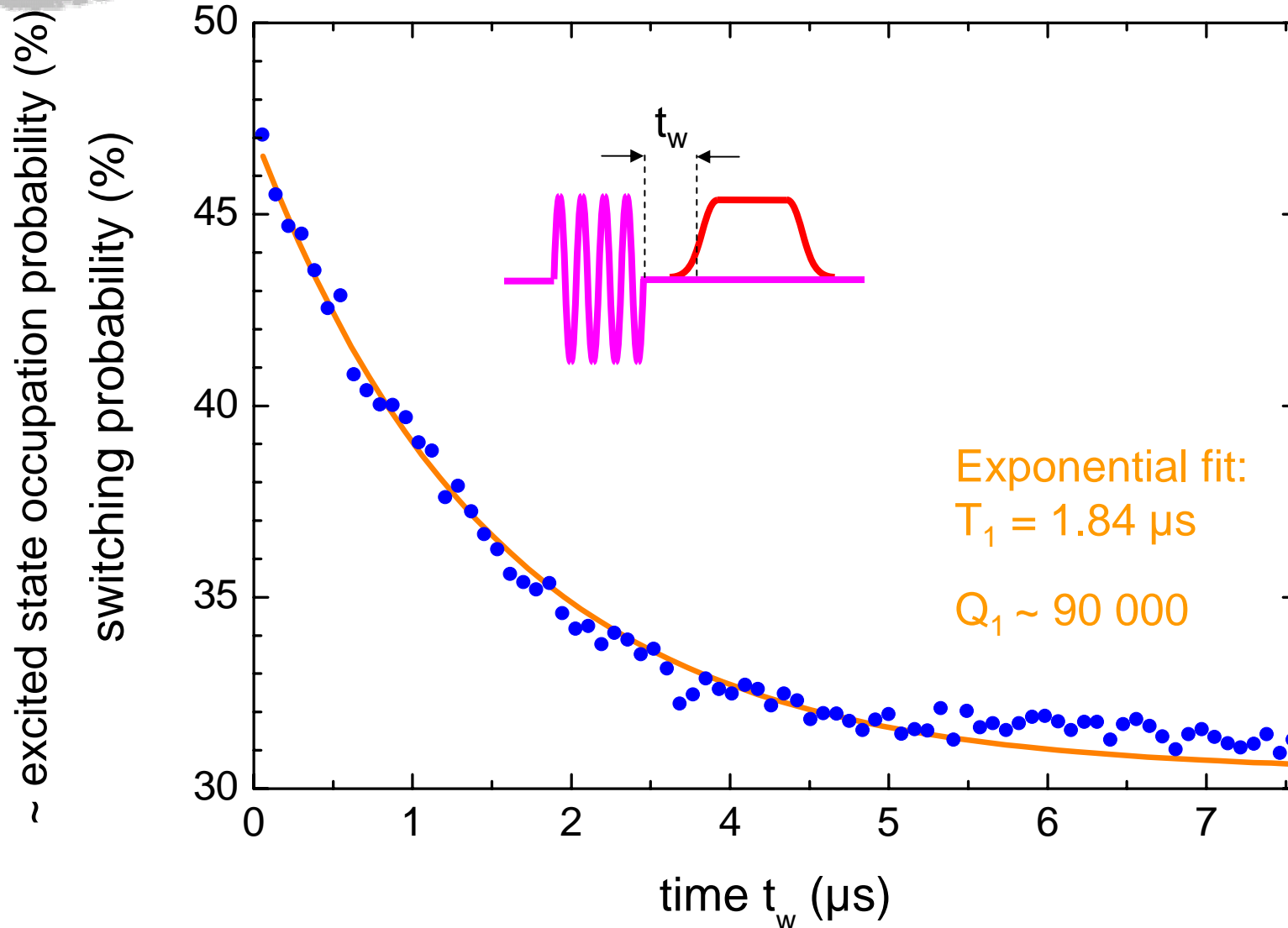
coherence time

$$T_2 = (\Gamma_\phi + \Gamma_1/2)^{-1}$$

Measuring Relaxation



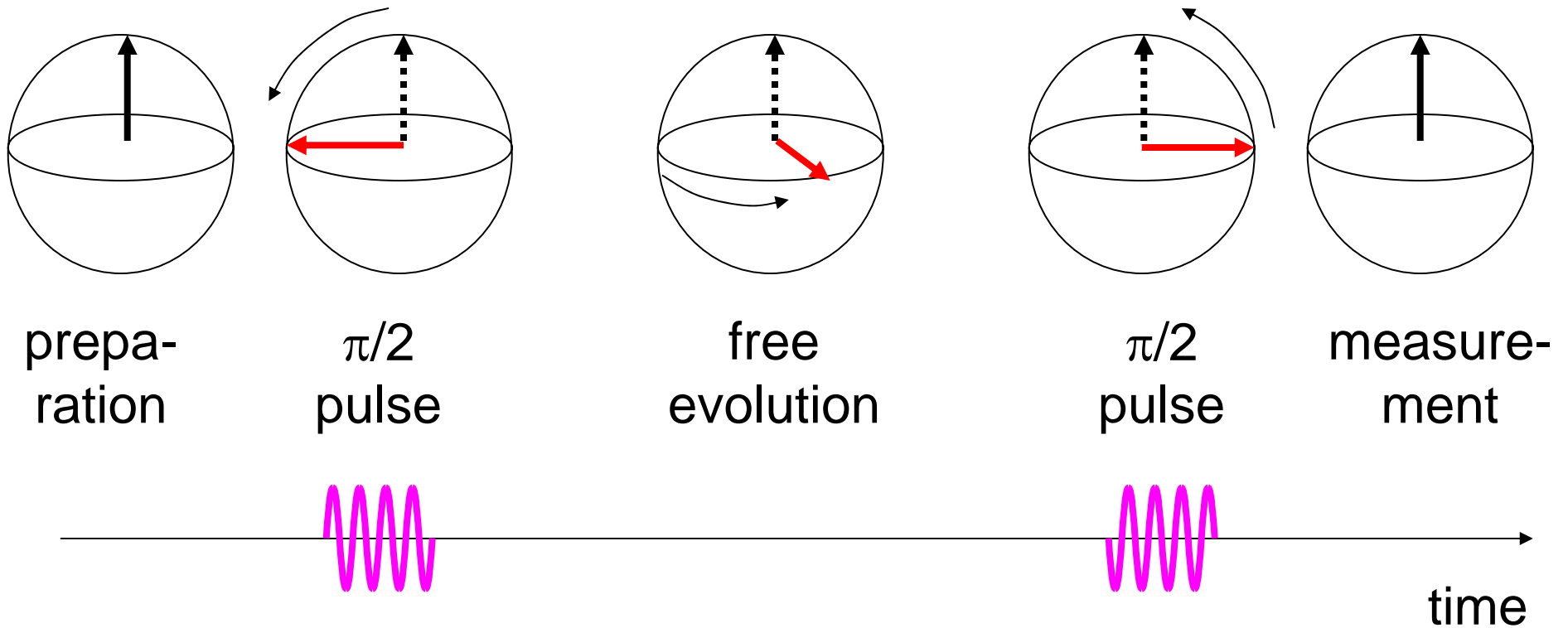
Relaxation Measurement



Measuring Quantum Coherence (I)



Ramsey fringe experiment



prepa-
ration

$\pi/2$
pulse

free
evolution

$\pi/2$
pulse

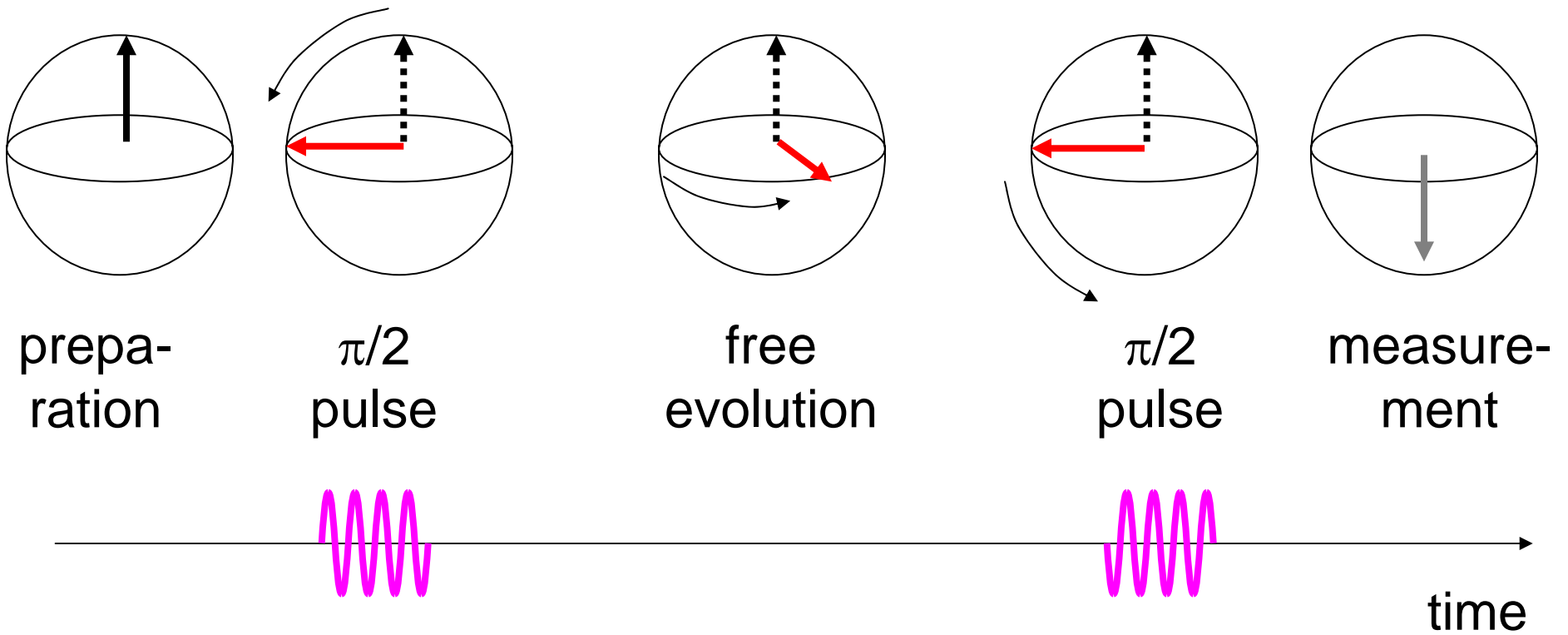
measure-
ment

determine coherence time T_2

Measuring Quantum Coherence (II)

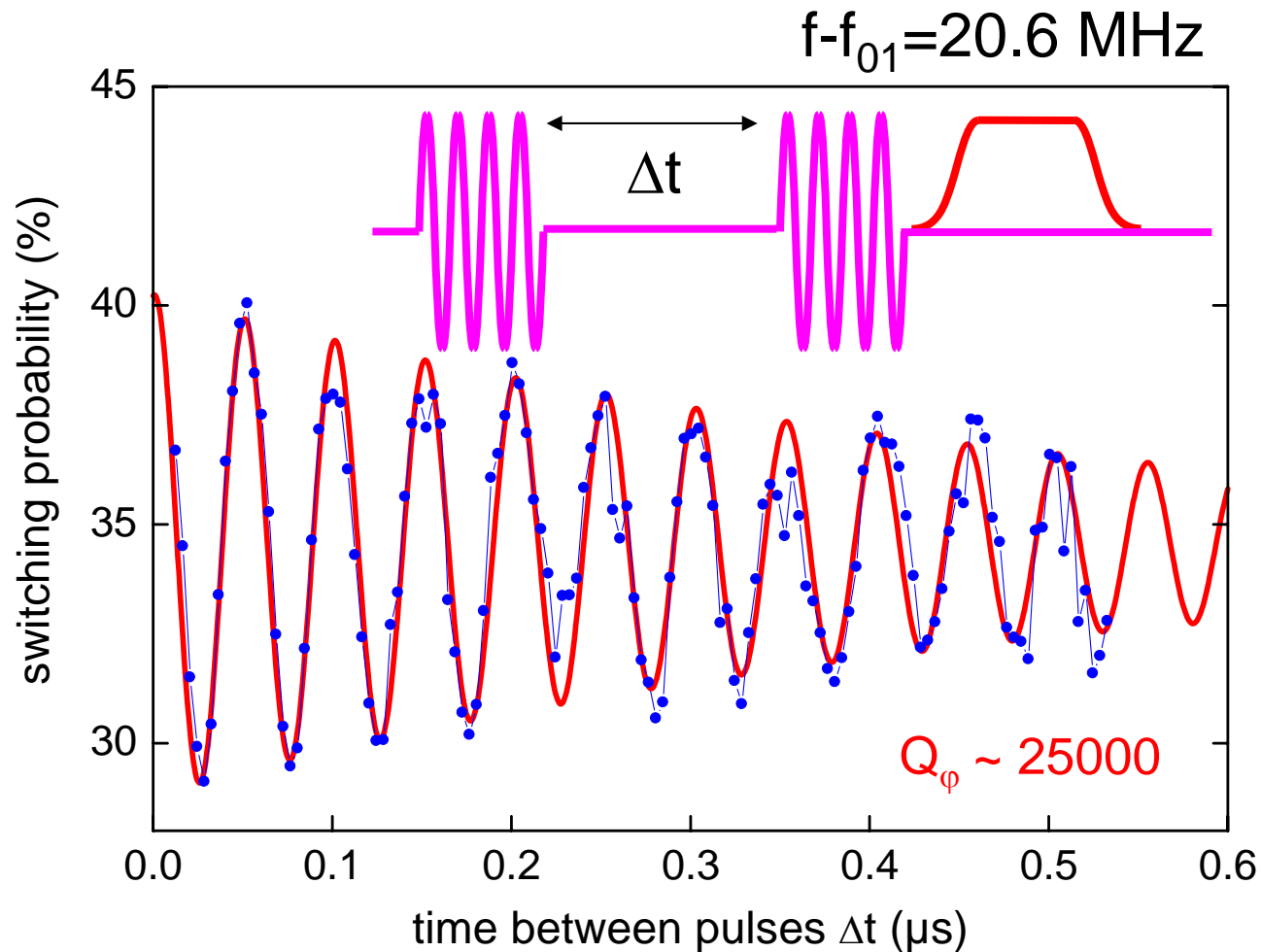


Ramsey fringe experiment



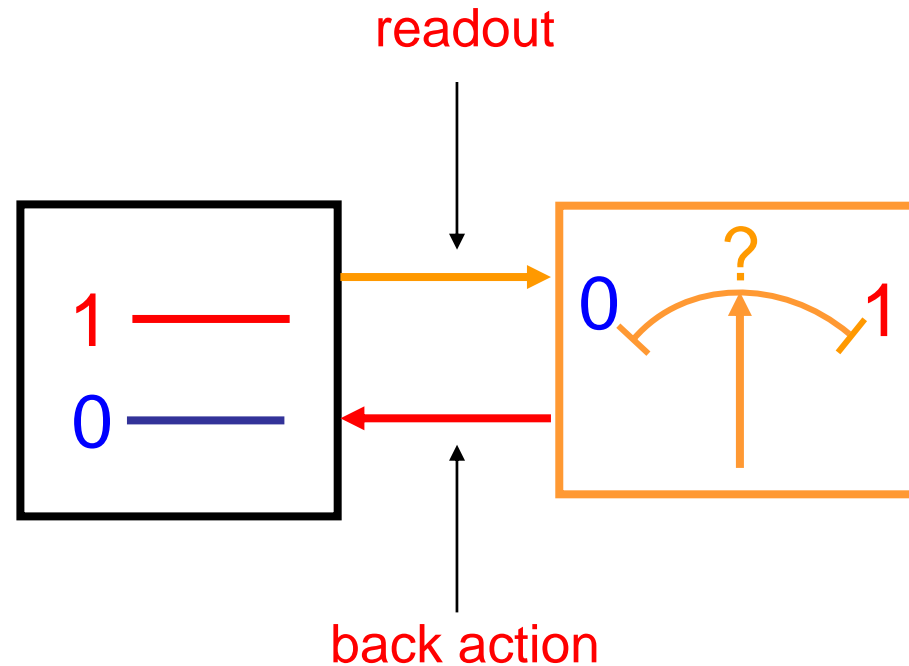
determine coherence time T_2

Measurement of Ramsey Fringes



D. Vion, A. Aassime, A. Cottet, ... , D. Esteve, and M.H. Devoret, *Science* **296**, 286 (2002).

Qubit Readouts

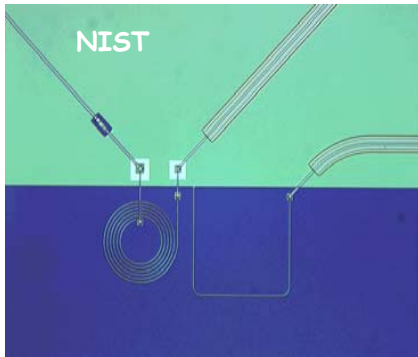


- negligible coupling between readout and qubit in OFF state
 - no dephasing, no relaxation
- strong coupling in ON state
 - minimal relaxation (QND)
 - high fidelity

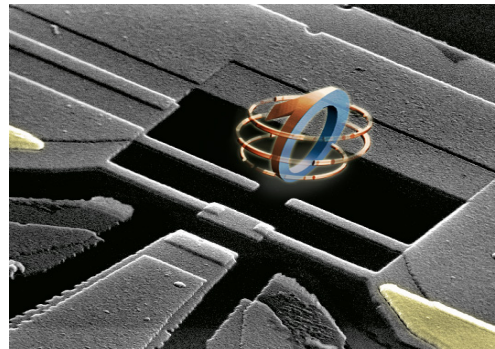
Readouts for Superconducting Qubits



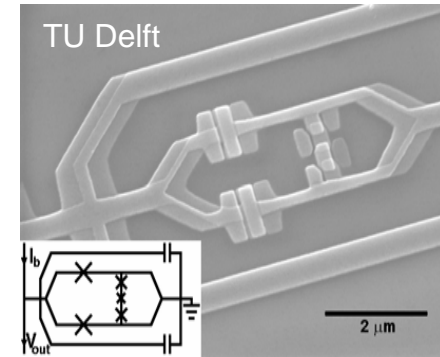
phase



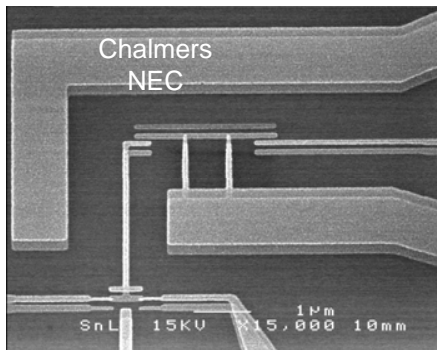
charge-phase



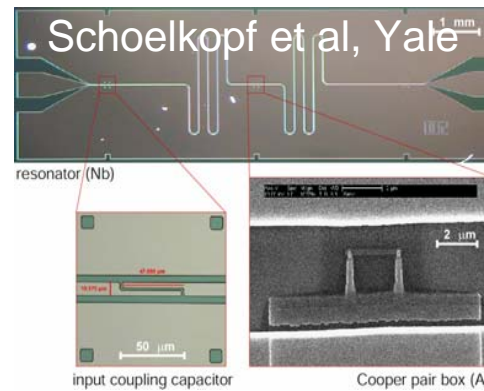
flux



charge



dispersive charge



Phase Qubit Direct Tunneling Readout



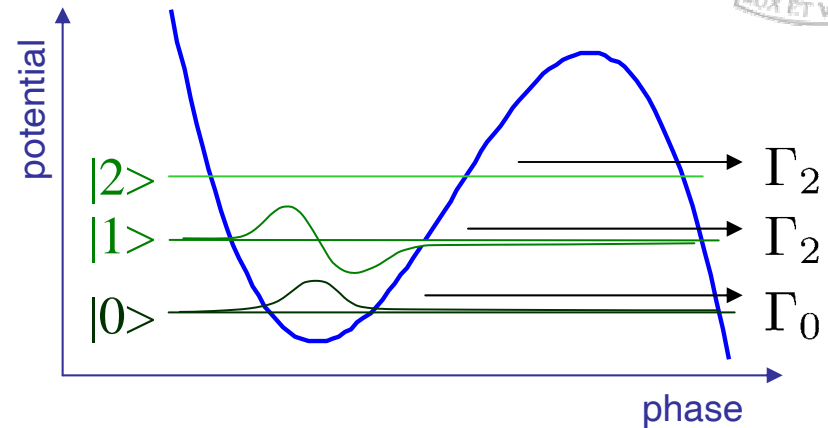
tunneling rates

$$\Gamma_2 \gg \Gamma_1 \gg \Gamma_0$$

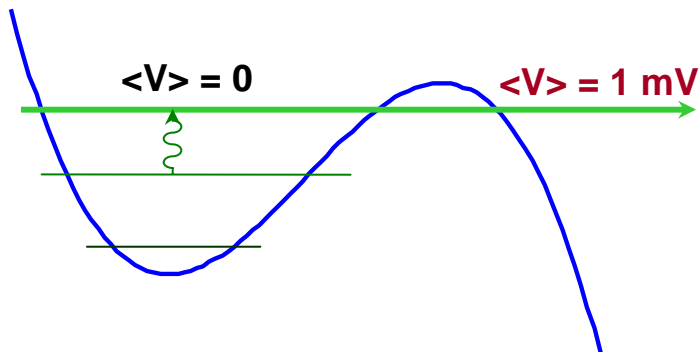
state measurement :

$|0\rangle$: zero voltage

$|1\rangle$: voltage



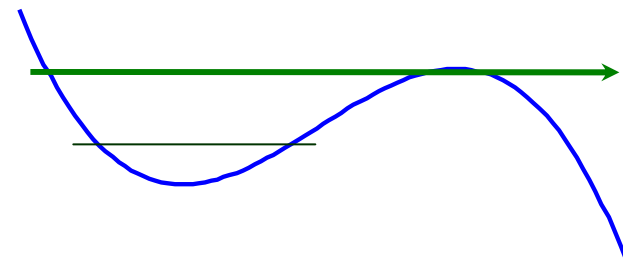
pump&probe: ω_{21} microwave pulse



advantages:

on-chip built-in amplification

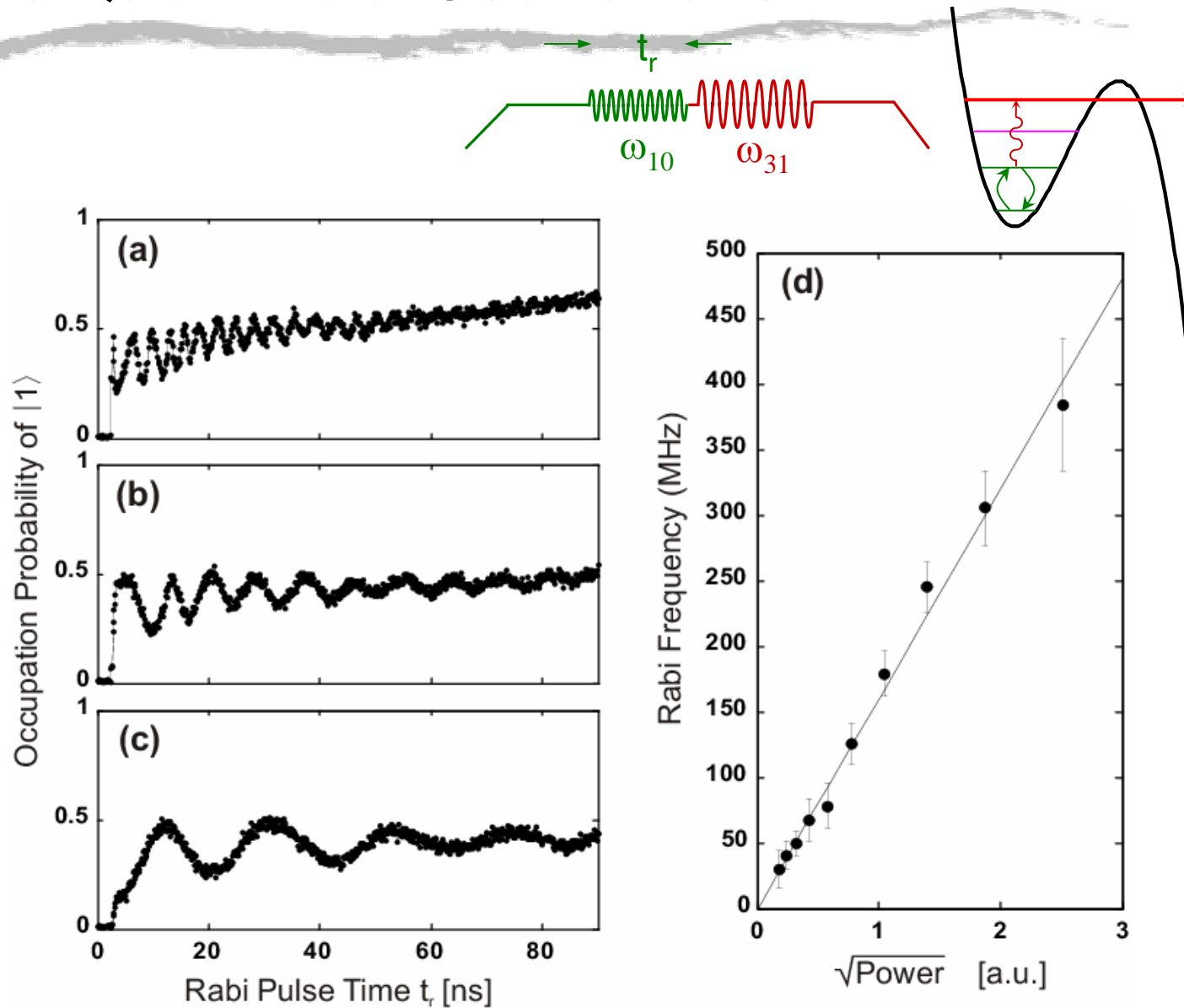
current pulse (lower barrier)



disadvantages:

- on-chip dissipation
- quasi particle generation
- decoherence

Phase Qubit: Rabi Oscillations

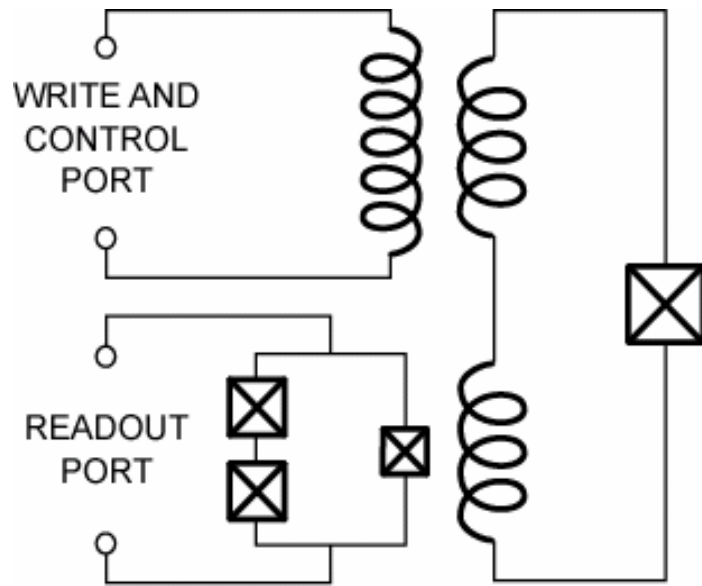


J. M. Martinis, S. Nam, J. Aumentado, and C. Urbina, *Phys. Rev. Lett.* **89**, 117901 (2002)

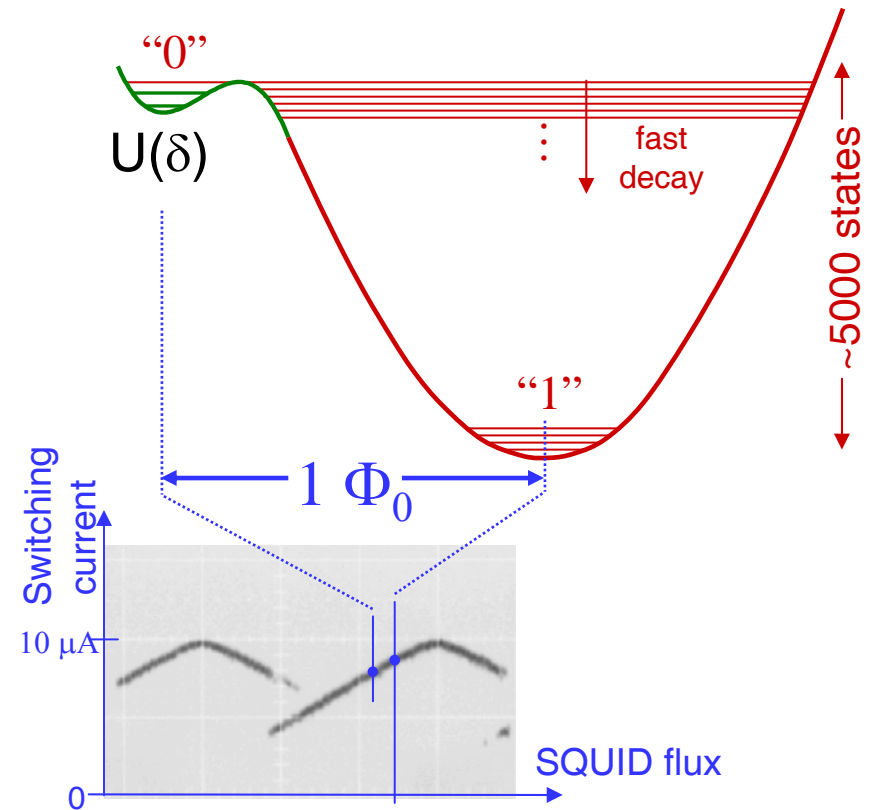
Phase Qubit SQUID Readout



tunneling readout with on-chip DC-SQUID amplifier

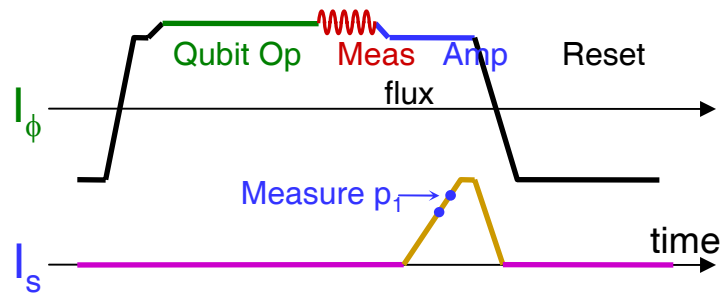


- sample and hold readout
- no quasi particles

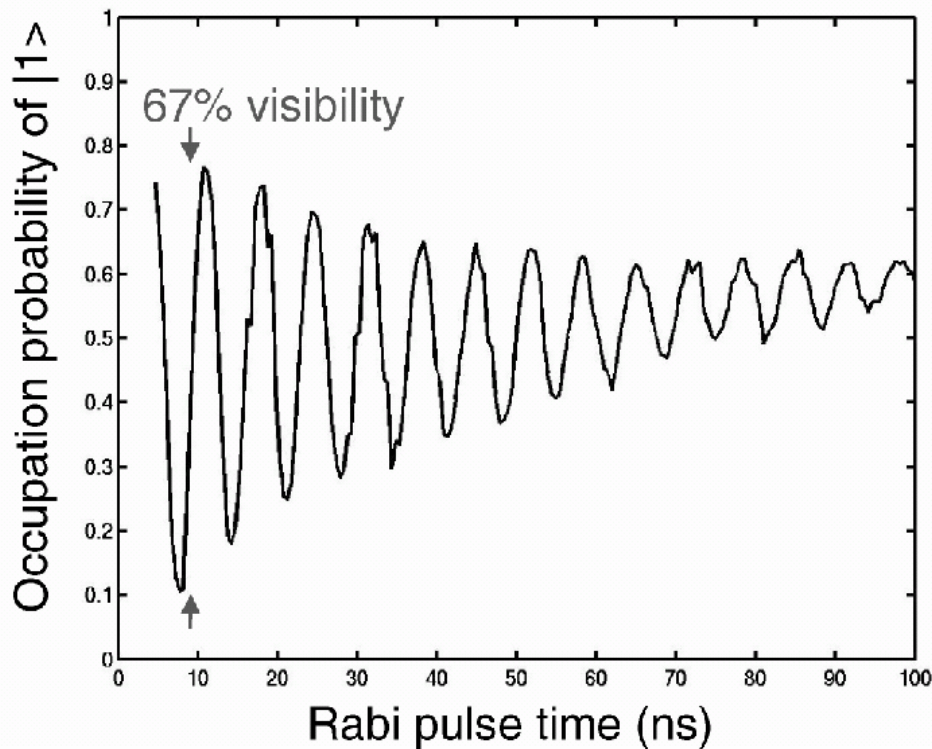




Phase Qubit: Rabi oscillations

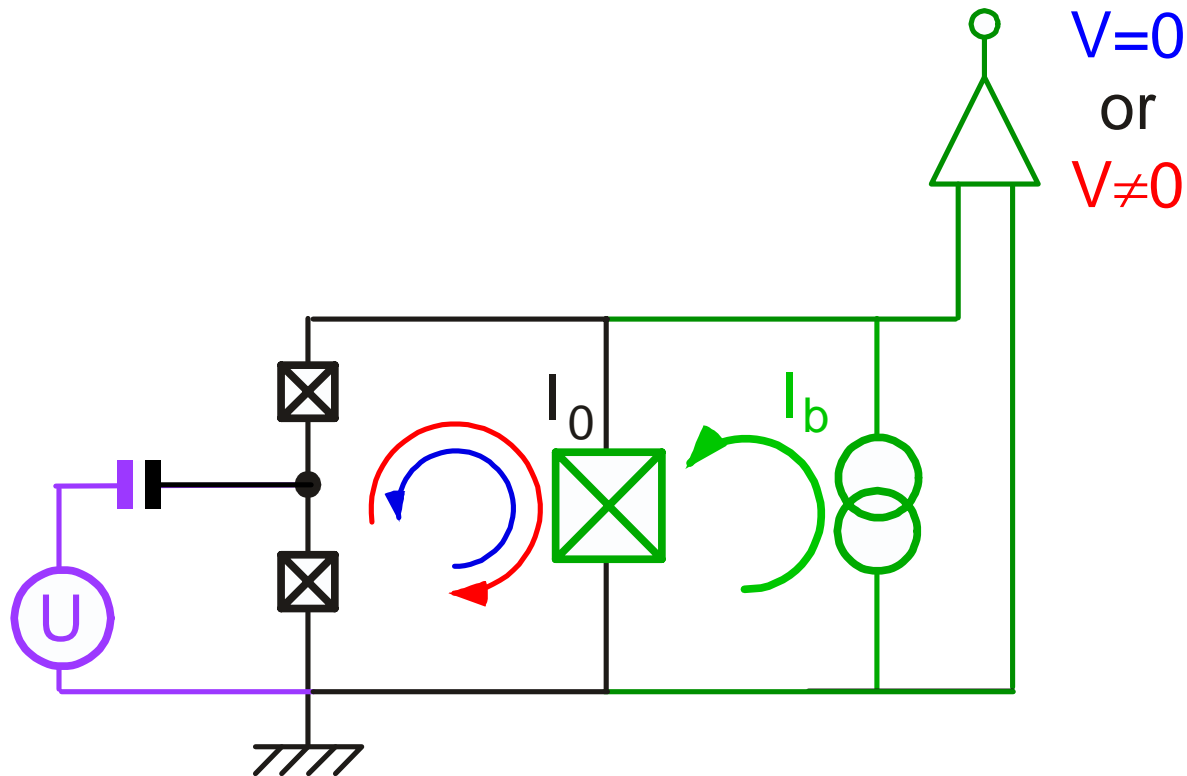


qubit cycle



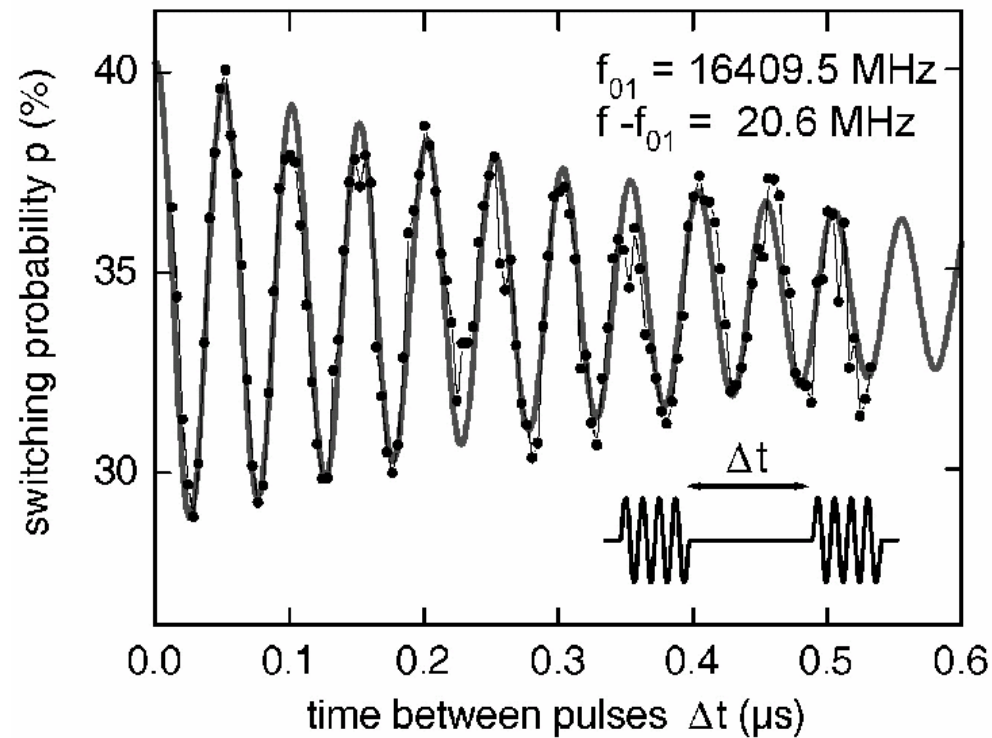
large visibility

Cooper Pair Box Readout: Quantronium



- high impedance capacitively coupled write and control port
- low impedance inductive readout

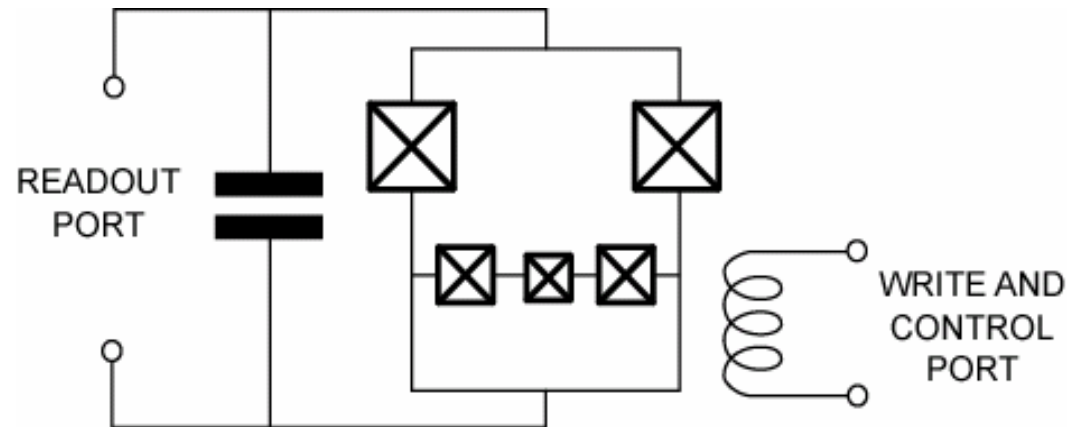
Ramsey oscillations in the Quantronium



- operation at optimal point
- long coherence time

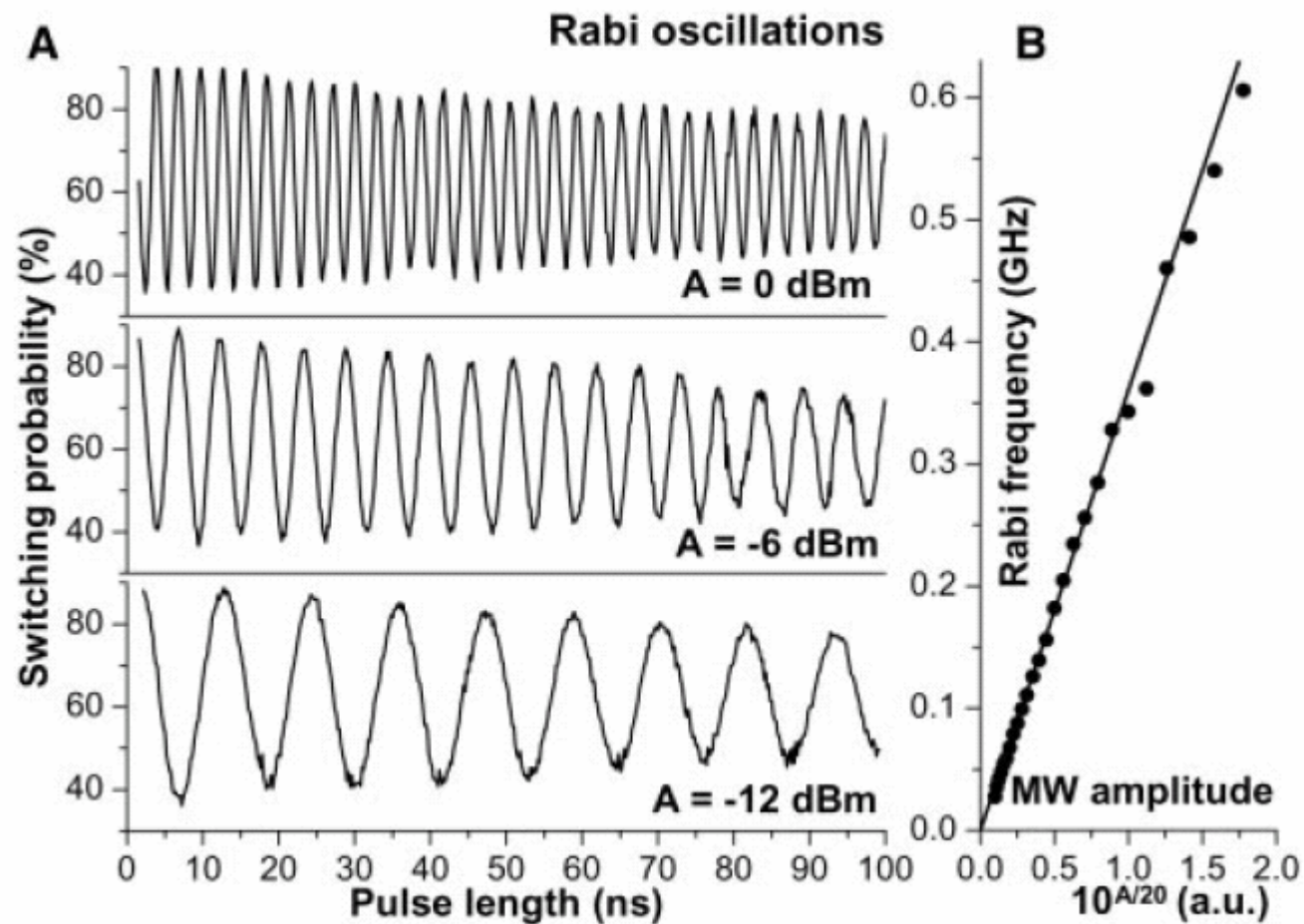
D. Vion, A. Aassime, A. Cottet, ... , D. Esteve, and M.H. Devoret, *Science* **296**, 286 (2002).

Flux Qubit with Built-In Readout



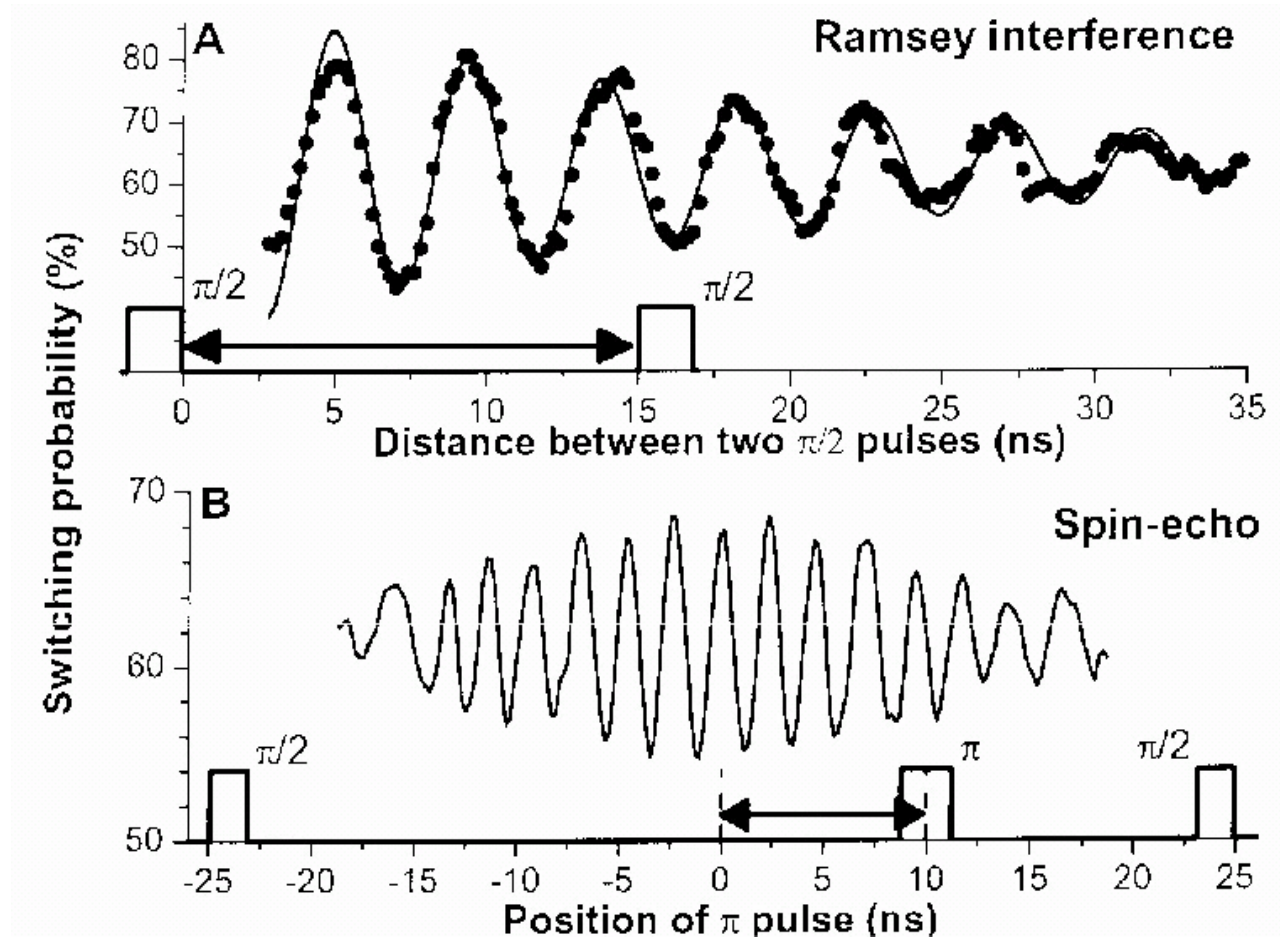
- inductively coupled hysteretic DC-SQUID for readout
- high impedance inductive write and control port

Rabi Oscillations with Flux Qubit



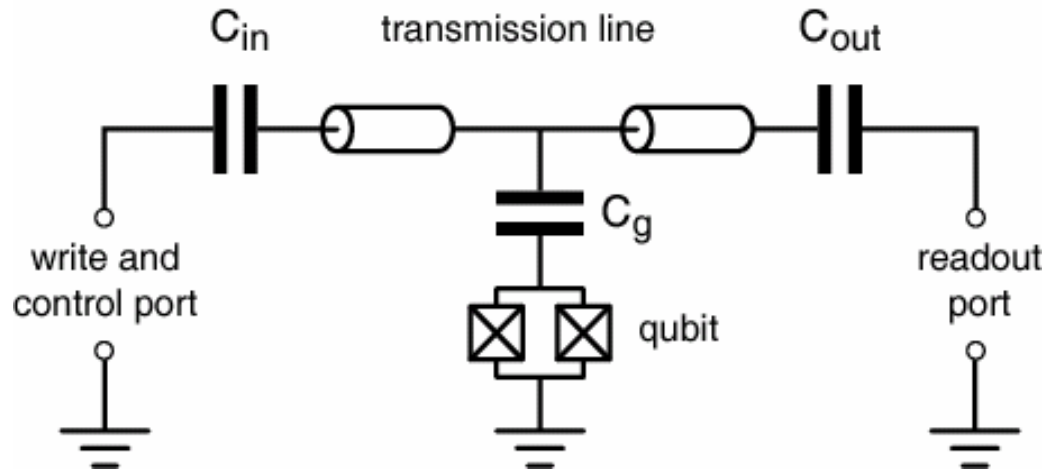
I. Chiorescu, Y. Nakamura, C. J. P. M. Harmans, and J. E. Mooij, *Science* **299**, 1869 (2003).

Ramsey Fringes with Flux Qubit



I. Chiorescu, Y. Nakamura, C. J. P. M. Harmans, and J. E. Mooij, *Science* **299**, 1869 (2003).

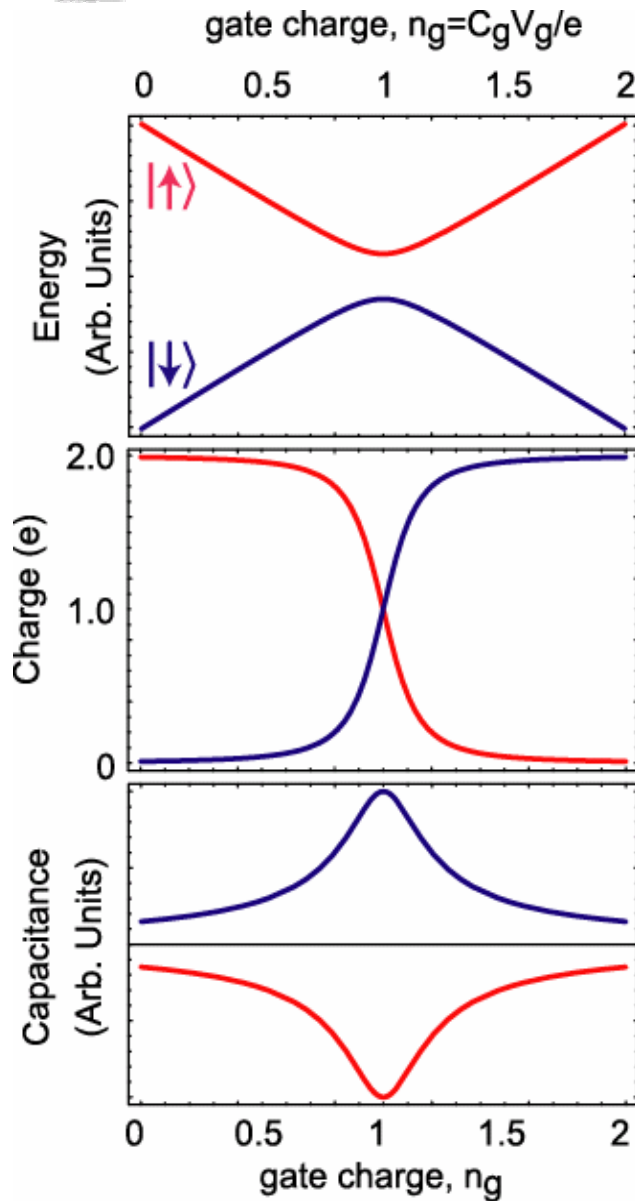
Dispersive Read-Out of Charge Qubit



- dispersive measurement of qubit susceptibility
- no on-chip dissipation
- quantum non-demolition measurement (QND)
- measurement back-action understood



The CPB: State Dependent Capacitance



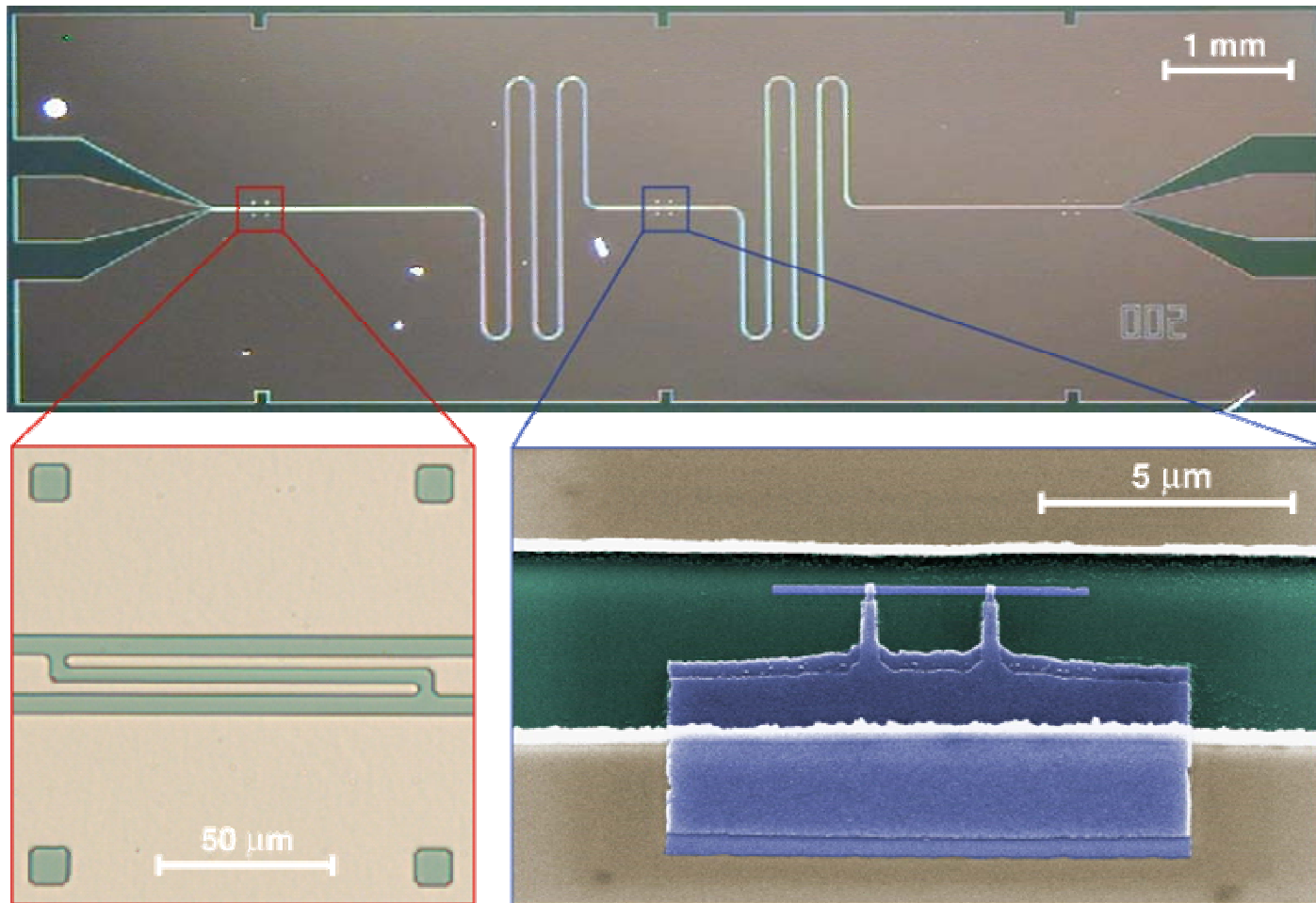
$$E = \frac{1}{2}CV^2$$

$$\frac{dE}{dV} = CV = Q$$

$$\frac{d^2E}{dV^2} = C$$

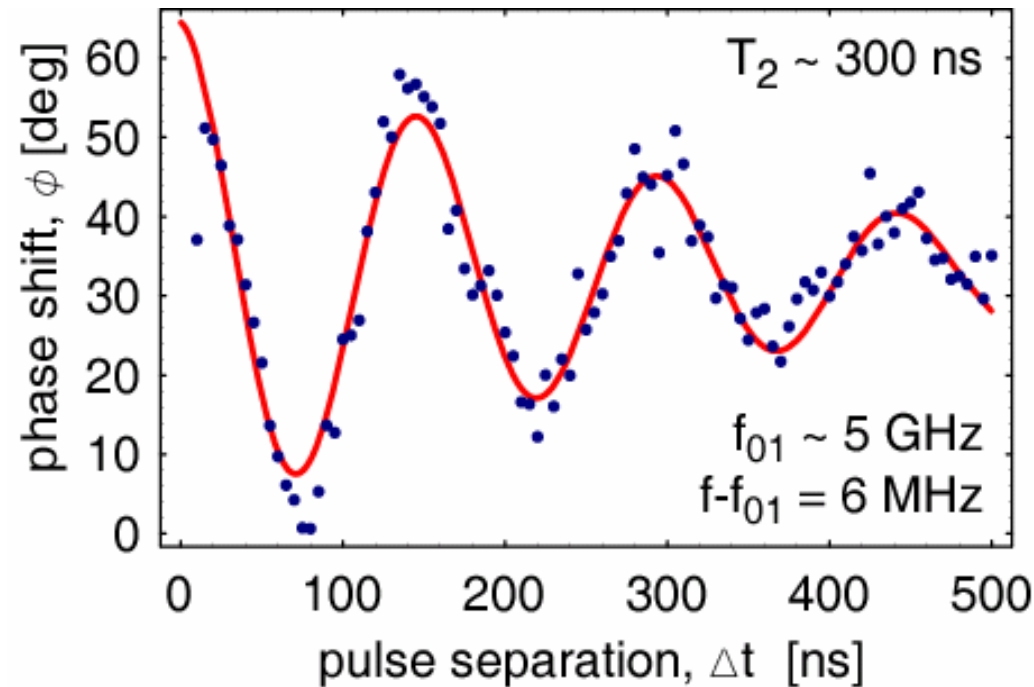
- n_g -dependent capacitance
- induces shift in resonator ν_r
- at magic point ($n_g = 1$)
- minimal dephasing
- no charge signal
- BUT maximum phase shift

A Cooper Pair Box in a Cavity



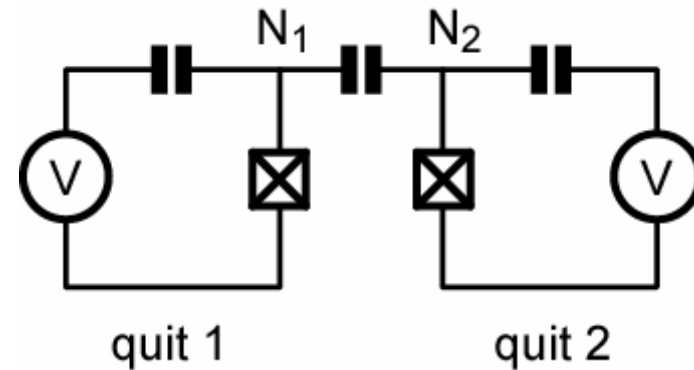
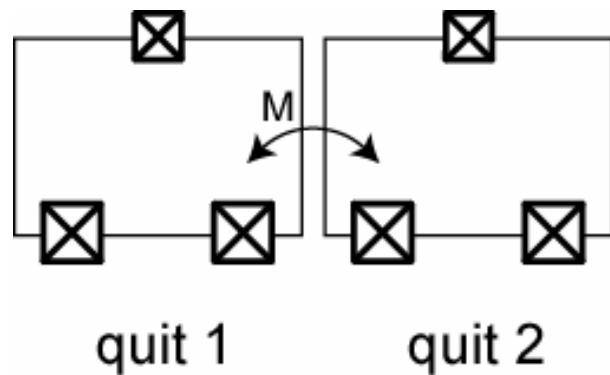
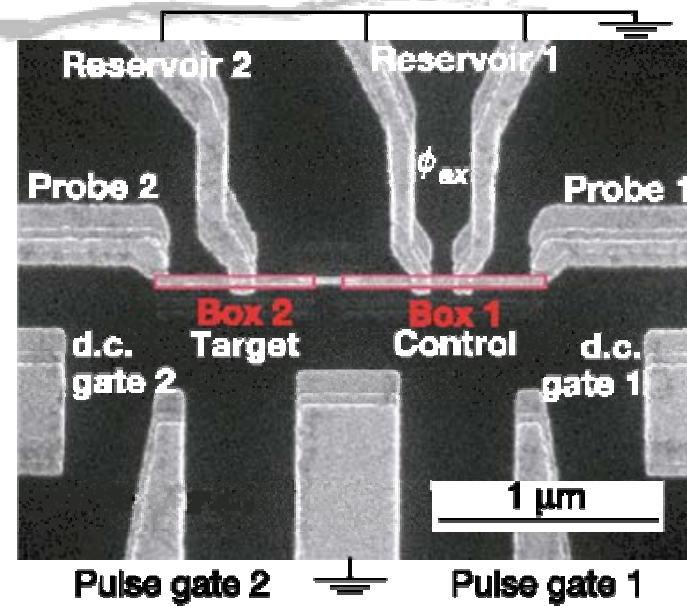
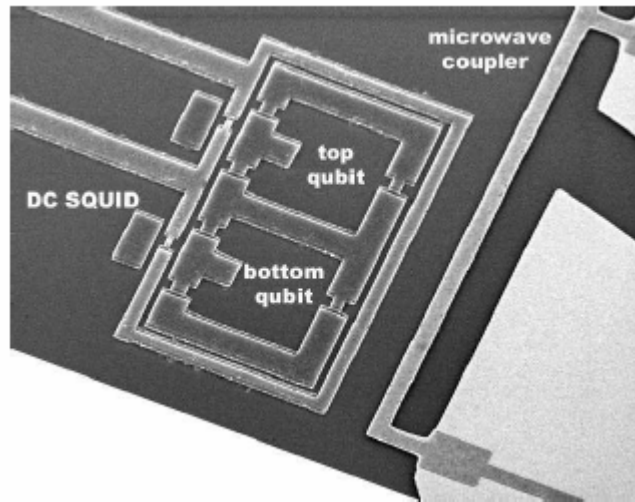
realization of superconducting cavity QED circuit

Ramsey Fringes with Circuit QED Readout



- long life time $T_1 \sim 5 \mu\text{s}$
- long coherence time

Realizations of Coupled Qubits



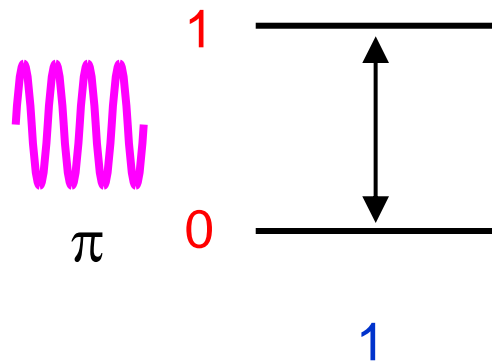
J. B. Majer, F. G. Paauw, A. C. J. ter Haar, C. P. J. Harmans, J. E. Mooij, cond-mat/0308192.
 Pashkin Yu. A., ... , Nakamura Y., Averin D. V., and Tsai J. S., *Nature* **421**, 823-826 (2003).

Coupled Qubits

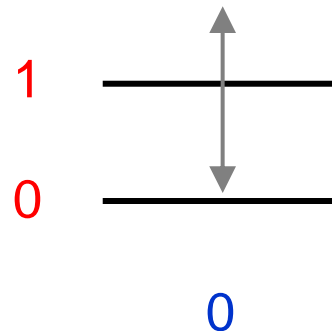


$$\begin{aligned}
 H &= \frac{E_{z1}}{2}\sigma_{z1} + \frac{E_{z2}}{2}\sigma_{z2} + J\sigma_{z1}\sigma_{z2} \\
 &= \frac{1}{2}(E_{z1} + 2J\sigma_{z2})\sigma_{z1} + \frac{E_{z2}}{2}\sigma_{z2}
 \end{aligned}$$

Ising coupling

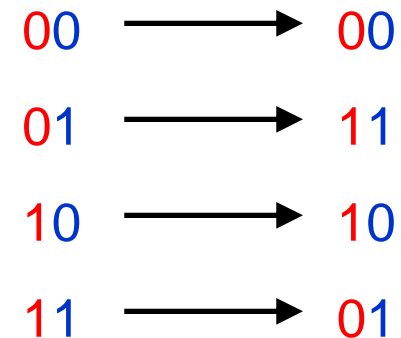


target bit (1)

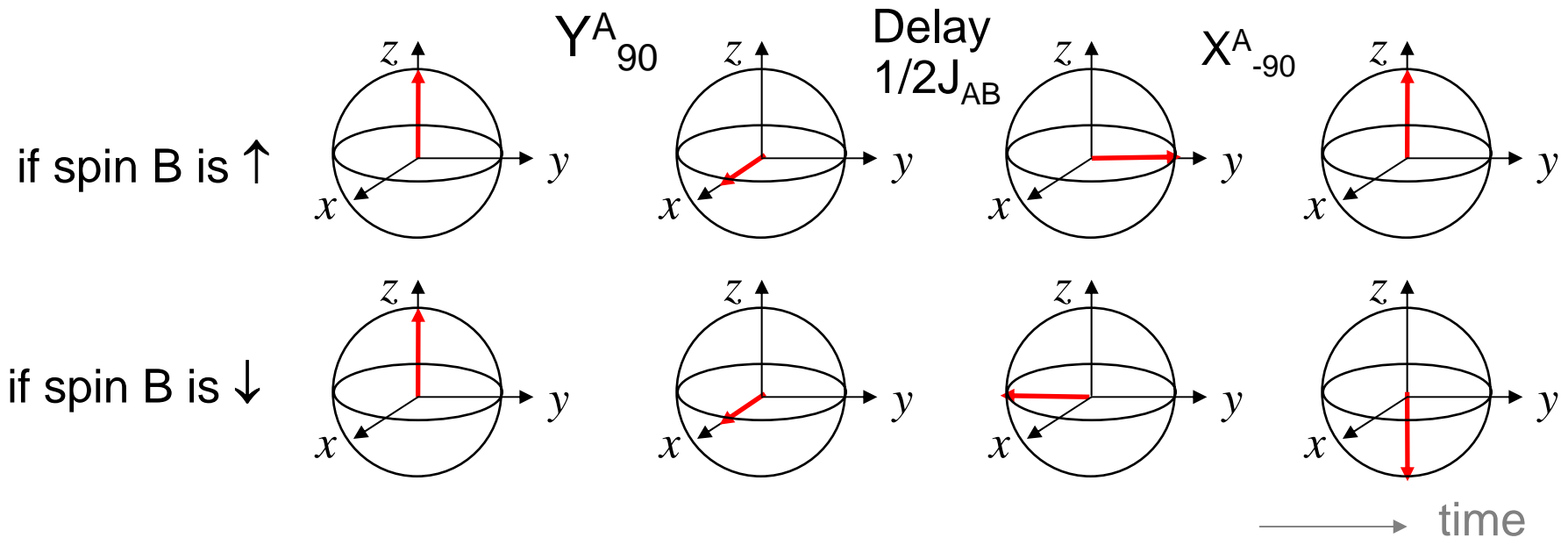
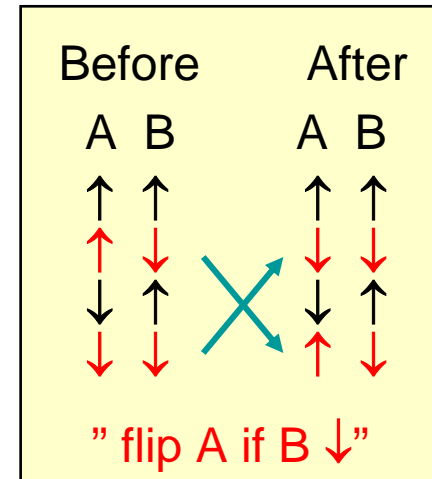
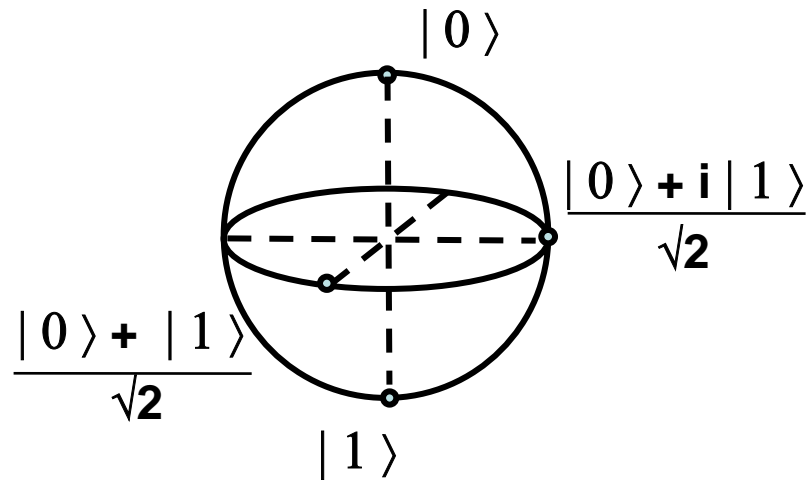


control bit (2)

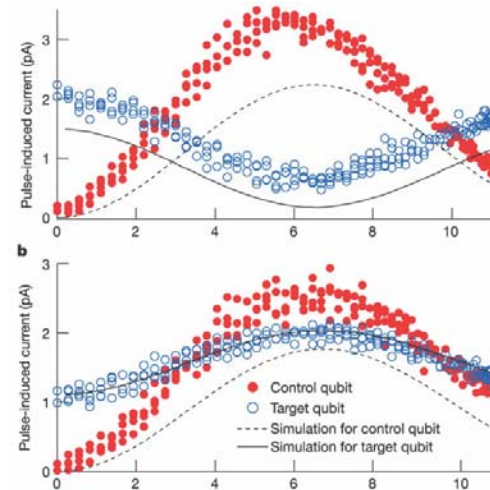
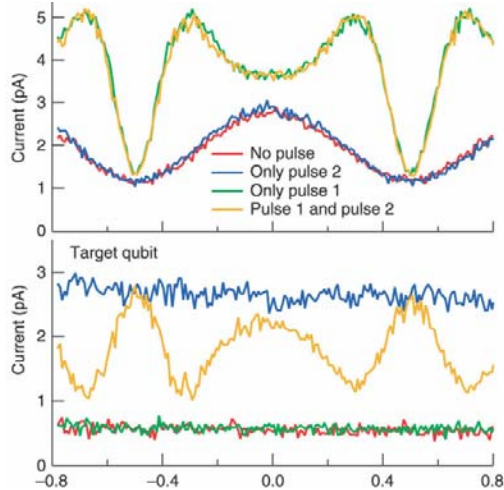
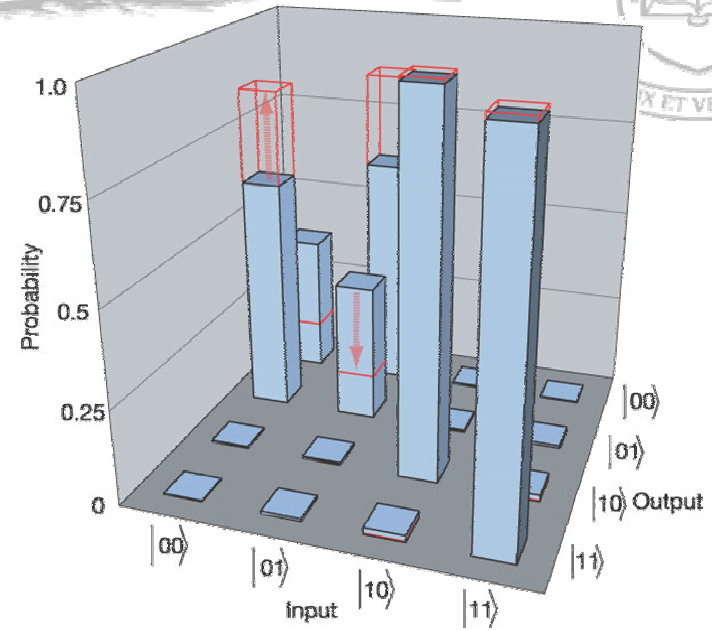
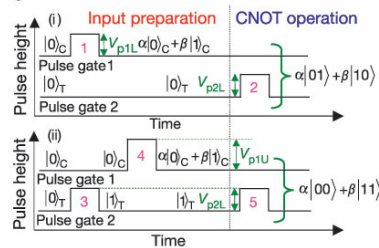
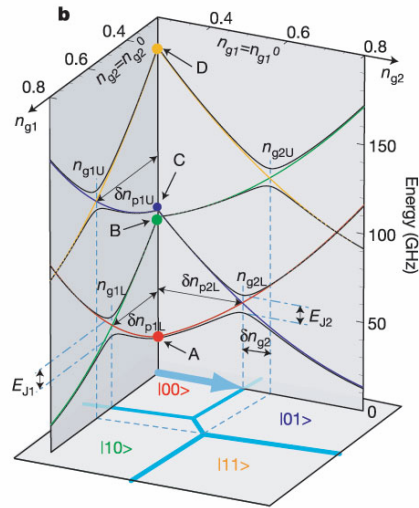
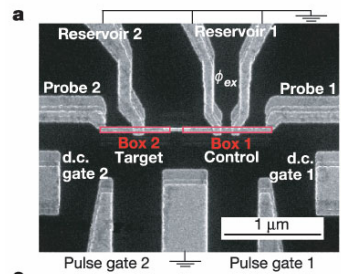
CNOT



2 Qubit Gates: Controlled-NOT



Realization of Controlled-NOT



T. Yamamoto, Yu. A. Pashkin, O. Astafiev, Y. Nakamura, J. S. Tsai *Nature* **425**, 941 (2003)

Conclusions

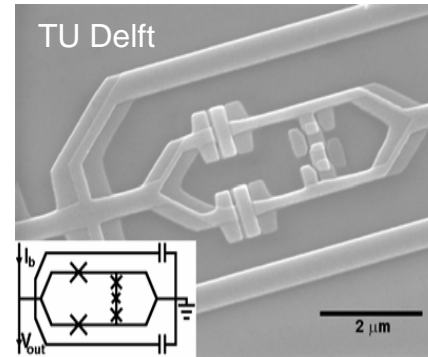
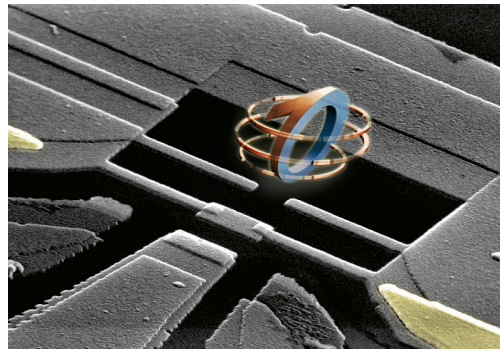
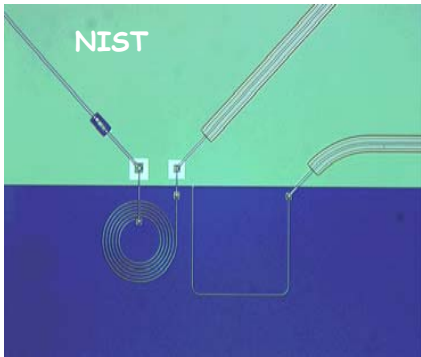


achievements:

- superconducting qubit architectures have been realized
- different readout strategies have been tested
- qubit initialization, single qubit control has been demonstrated
- first two-qubit gates have been implemented

challenges:

- realize high fidelity, single-shot qubit readout
- control decoherence (increase T_1 and T_2)
- understand limitations imposed by circuit materials and fabrication
- integrate multi-qubit circuits



many thanks to:

M. Devoret, D. Esteve, S. Girvin, J. Mooij, R. Schoelkopf, L. Vandersypen

